



## **General Description**

The MAX8744A/MAX8745A are dual step-down, switch-mode, power-supply (SMPS) controllers with synchronous rectification, intended for main 5V/3.3V power generation in battery-powered systems. Fixed-frequency operation with optimal interleaving minimizes input ripple current from the lowest input voltages up to the 26V maximum input. Optimal 40/60 interleaving allows the input voltage to go down to 8.3V before duty-cycle overlap occurs, compared to 180° out-of-phase regulators where the duty-cycle overlap occurs when the input drops below 10V.

Output current sensing provides peak current-limit protection, using either an accurate sense resistor or using lossless inductor DCR current sensing. A low-noise mode maintains high light-load efficiency while keeping the switching frequency out of the audible range.

An internal, fixed 5V, 100mA linear regulator powers up the MAX8744A/MAX8745A and their gate drivers, as well as external keep-alive loads. When the main PWM regulator is in regulation, an automatic bootstrap switch bypasses the internal linear regulator, providing current up to 200mA. An additional adjustable linear-regulator driver with an external pnp transistor can be used with a secondary winding to provide a 12V supply, or powered directly from the main outputs to generate low-voltage outputs as low as 1V.

Independent enable controls and power-good signals allow flexible power sequencing. Voltage soft-start gradually ramps up the output voltage and reduces inrush current, while soft-shutdown gradually ramps the output voltage down, preventing negative voltage dips. The MAX8744A/MAX8745A feature output undervoltage and thermal-fault protection. The MAX8744A also includes output overvoltage-fault protection.

The MAX8744A/MAX8745A are available in a 32-pin, 5mm x 5mm, thin QFN package. The exposed backside pad improves thermal characteristics for demanding linear keep-alive applications.

## Applications

Main Power Supplies
2 to 4 Li+ Cell Battery-Powered Devices
Notebook and Subnotebook Computers
PDAs and Mobile Communicators

Dual Mode is a trademark of Maxim Integrated Products, Inc.

### **Features**

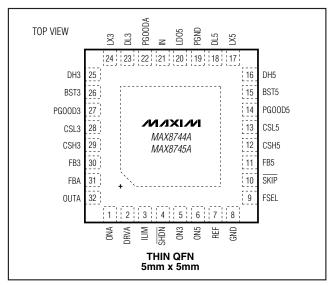
- **♦ Fixed-Frequency, Current-Mode Control**
- ♦ 40/60 Optimal Interleaving
- ♦ Internal BST Switches
- ♦ Internal 5V, 100mA Linear Regulator
- ♦ Auxiliary Linear-Regulator Driver (12V or Adjustable Down to 1V)
- ◆ Dual Mode™ Feedback—3.3V/5V Fixed or Adjustable Output Voltages
- ◆ 200kHz/300kHz/500kHz Switching Frequency
- ♦ Undervoltage and Thermal-Fault Protection
- ♦ Overvoltage-Fault Protection (MAX8744A Only)
- ♦ 6V to 26V Input Range
- ♦ 2V ±0.75% Reference Output
- Independent Enable Inputs and Power-Good Outputs
- ♦ Soft-Start and Soft-Shutdown (Voltage Ramp)
- ♦ 8µA (typ) Shutdown Current

## **Ordering Information**

PART	TEMP RANGE	PRANGE PIN- PACKAGE	
MAX8744AETJ+	-40°C to +85°C	32 Thin QFN (5mm x 5mm)	T3255-4
<b>MAX8745A</b> ETJ+*	-40°C to +85°C	32 Thin QFN (5mm x 5mm)	T3255-4

<sup>+</sup>Denotes a lead-free package.

## Pin Configuration



<sup>\*</sup>Future product—contact factory for availability.

### **ABSOLUTE MAXIMUM RATINGS**

IN, SHDN, DRVA, OUTA to GND LDO5, ON3, ON5, ONA to GND	
PGOODA, PGOOD3, PGOOD5 to G	
CSL3, CSH3, CSL5, CSH5 to GND.	0.3V to +6V
REF, FB3, FB5, FBA to GND	0.3V to (V <sub>LDO5</sub> + 0.3V)
SKIP, FSEL, ILIM to GND	0.3V to (V <sub>LDO5</sub> + 0.3V)
DL3, DL5 to PGND	0.3V to (V <sub>LDO5</sub> + 0.3V)
BST3, BST5 to PGND	0.3V to +34V
BST3 to LX3	0.3V to +6V
DH3 to LX3	0.3V to (V <sub>BST3</sub> + 0.3V)
BST5 to LX5	
DH5 to LX5	0.3V to (V <sub>BST5</sub> + 0.3V)
GND to PGND	

DOTO DOTE L LDOE	0.01/1
BST3, BST5 to LDO5	
LDO Short Circuit to GND	Momentary
REF Short Circuit to GND	
DRVA Current (Sinking)	30mÅ
OUTA Shunt Current	30mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
Multilayer PCB	
32-Pin, 5mm x 5mm TQFN	
(derated 34.5mW/°C above +70°C)	2459mW
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5, I<sub>REF</sub> = I<sub>LDO5</sub> = I<sub>OUTA</sub> = no load, **T<sub>A</sub>** = **0°C** to **+85°C**, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL	. CONDITIONS		TYP	MAX	UNITS
INPUT SUPPLIES (Note 1)	l .	-				
Viv. Input Voltage Denge	V/v.	LDO5 in regulation	5.4		26.0	V
V <sub>IN</sub> Input Voltage Range	VIN	IN = LDO5, V <sub>CSL5</sub> < 4.4V	4.5		5.5	V
V <sub>IN</sub> Operating Supply Current	I <sub>IN</sub>	LDO5 switched over to CSL5, either SMPS on		20	36	μΑ
V <sub>IN</sub> Standby Supply Current	lin(STBY)	$V_{IN} = 6V$ to 26V, both SMPS off, includes $ SHDN $		65	120	μΑ
V <sub>IN</sub> Shutdown Supply Current	IN(SHDN)	V <sub>IN</sub> = 6V to 26V		8	20	μΑ
Quiescent Power Consumption	PQ	Both SMPS on, FB3 = FB5 = LDO5, SKIP = GND, V <sub>CSL3</sub> = 3.5V, V <sub>CSL5</sub> = 5.3V, V <sub>OUTA</sub> = 15V, P <sub>IN</sub> + P <sub>CSL3</sub> + P <sub>CSL5</sub> + P <sub>OUTA</sub>		3.5	4.5	mW
MAIN SMPS CONTROLLERS						
3.3V Output Voltage in Fixed Mode	V <sub>OUT3</sub>	V <sub>IN</sub> = 6V to 26V, SKIP = FB3 = LDO5, 0 < V <sub>CSH3</sub> - V <sub>CSL3</sub> < 50mV (Note 2)	3.265	3.315	3.365	V
5V Output Voltage in Fixed Mode	V <sub>OUT5</sub>	$V_{IN} = 6V \text{ to } 26V, \overline{SKIP} = FB5 = LDO5, \\ 0 < V_{CSH5} - V_{CSL5} < 50mV \text{ (Note 2)}$	4.94	5.015	5.09	V
Feedback Voltage in Adjustable	\/	V <sub>IN</sub> = 6V to 26V, FB3 or FB5 duty factor = 20% to 80%	1.980	2.010	2.040	V
Mode (Note 2)	V <sub>FB</sub> _	V <sub>IN</sub> = 6V to 26V, FB3 or FB5 duty factor = 50%	1.990	2.010	2.030	V

## **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5, I<sub>REF</sub> = I<sub>LDO5</sub> = I<sub>OUTA</sub> = no load,  $T_A$  = 0°C to +85°C, unless otherwise noted. Typical values are at  $T_A$  = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Output Voltage Adjust Range		Either SMPS		2.0		5.5	V	
FB3, FB5 Dual Mode Threshold				3.0	V <sub>LOO5</sub> - 1.0	V <sub>LOO5</sub> - 0.4	V	
Feedback Input Leakage Current		$V_{FB3} = V_{FB5} = 2.1$	V	-0.1		+0.1	μΑ	
DC Load Regulation		Either SMPS, SKIP 0 < V <sub>CSH</sub> V <sub>CSL</sub> _			-0.1		%	
Line Regulation Error		Either SMPS, 6V <	V <sub>IN</sub> < 26V		0.03		%/V	
		FSEL = GND		170	200	230		
Operating Frequency (Note 1)	fosc	FSEL = REF		270	300	330	kHz	
		FSEL = LDO5		425	500	575		
Maximum Duty Factor	D <sub>MAX</sub>	(Note 1)		97.5	99		%	
Minimum On-Time	tonmin				100		ns	
SMPS3-to-SMPS5 Phase Shift		SMPS5 starts after	SMPS3		40		%	
CIVII GO TO CIVII GO I FIGGO GIIII		OWN GO Starto artor	OWII GO		144		Deg	
CURRENT LIMIT	1	T		•			Ī	
ILIM Adjustment Range				0.5		V <sub>REF</sub>	V	
Current-Sense Input Leakage Current		CSH3 = CSH5 = G	IND or LDO5	-1		+1	μΑ	
Current-Limit Threshold (Fixed)	V <sub>LIMIT</sub>	V <sub>CSH</sub> V <sub>CSL</sub> _, ILI	M = LDO5	45	50	55	mV	
Current-Limit Threshold	VLIMIT	VCSH VCSL_	VILIM = 2.00V	185	200	215	mV	
(Adjustable)	V LIMI I		$V_{ILIM} = 1.00V$	94	100	106	1110	
Current-Limit Threshold		V <sub>CSH</sub> V <sub>CSL</sub> _, SK	(IP = ILIM = LDO5	-67	-60	-53	mV	
(Negative)	VNEG	V <sub>CSH</sub> - V <sub>CSL</sub> , <del>SKIP</del> = LDO5, adjustable mode, percent of current limit				-120		%
Current-Limit Threshold (Zero Crossing)	V <sub>Z</sub> X	V <sub>CSH</sub> - V <sub>CSL</sub> , SK ILIM = LDO5	IP = GND,	0	3	6	mV	
			ILIM = LDO5	6	10	14	mV	
Idle Mode™ Threshold	VIDLE	$\frac{V_{CSH\_} - V_{CSL\_}}{SKIP} = GND$	With respect to current-limit threshold (V <sub>LIMIT</sub> )		20		%	
			ILIM = LDO5	2.5	5	7.5	mV	
Idle Mode Threshold (Low Audible-Noise Mode)	VIDLE	VCSHL - VCSL_, SKIP = REF	With respect to current-limit threshold (V <sub>LIMIT</sub> )		10		%	
ILIM Leakage Current		ILIM = GND or REF	F	-1		+1	μΑ	

Idle Mode is a trademark of Maxim Integrated Products, Inc.

## **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5,  $I_{REF}$  =  $I_{LDO5}$  =  $I_{OUTA}$  = no load,  $T_A$  =  $0^{\circ}$ C to +85°C, unless otherwise noted. Typical values are at  $T_A$  = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Soft-Start Ramp Time	<sup>t</sup> SSTART	Measured from the rising edge of ON_ to full scale		2		ms
Soft-Stop Ramp Time	tsstop	Measured from the falling edge of ON_ to full scale		4		ms
INTERNAL FIXED LINEAR REGUL	ATORS					
LDO5 Output Voltage	V <sub>LDO5</sub>	ON5 = GND, 6V < V <sub>IN</sub> < 26V, 0 < I <sub>LDO5</sub> < 100mA	4.85	4.95	5.10	V
LDO5 Undervoltage-Lockout Fault		Rising edge, hysteresis = 1%	3.7	4.0	4.1	V
Short-Circuit Current (Switched Over to CSL5)		LDO5 = GND, V <sub>CSL5</sub> > 4.7V	200	425		mA
AUXILIARY LINEAR REGULATOR	•					I.
DRVA Voltage Range	V <sub>DRVA</sub>		0.5		26.0	V
DDVA D : O .		V <sub>FBA</sub> = 1.05V, V <sub>DRVA</sub> = 5V			0.4	
DRVA Drive Current		V <sub>FBA</sub> = 0.965V, V <sub>DRVA</sub> = 5V	10			mA
FBA Regulation Threshold	V <sub>FBA</sub>	V <sub>DRVA</sub> = 5V, I <sub>DRVA</sub> = 1mA (sink)	0.98	1.00	1.02	V
FBA Load Regulation		$V_{DRA} = 5V$ , $I_{DRVA} = 0.5$ mA to 5mA		-1.2	-2.2	%
OUTA Shunt Trip Level		Rising edge	25	26	27	V
FBA Leakage Current		V <sub>FBA</sub> = 1.035V	-0.1		+0.1	μΑ
Secondary Feedback Regulation Threshold		VDRVA - VOUTA		0		V
DL5 Pulse Width				1/ 3f <sub>OSC</sub>		μs
OUTA Leakage Current	Iouta	V <sub>DRVA</sub> = V <sub>OUTA</sub> = 25V			50	μΑ
REFERENCE (REF)						
Reference Voltage	V <sub>REF</sub>	LDO5 in regulation, I <sub>REF</sub> = 0	1.985	2.00	2.015	V
Reference Load-Regulation Error	$\Delta V_{REF}$	$I_{REF} = -5\mu A$ to $+50\mu A$	-10		+10	mV
REF Lockout Voltage	V <sub>REF</sub> (UVLO)	Rising edge		1.8		V
FAULT DETECTION						
Output Overvoltage Trip Threshold (MAX8744A Only)		With respect to error-comparator threshold	8	11	14	%
Output Overvoltage Fault Propagation Delay (MAX8744A Only)	tovp	50mV overdrive		10		μs

## **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5, IREF = ILDO5 = IOUTA = no load,  $T_A$  = 0°C to +85°C, unless otherwise noted. Typical values are at  $T_A$  = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Output Undervoltage Protection Trip Threshold		With respect to error-compara threshold	ator	65	70	75	%	
Output Undevoltage Fault Propagation Delay	tuvp	50mV overdrive			10		μs	
Output Undervoltage Protection Blanking Time	tBLANK	From rising edge of ON_ with fsw	respect to	5000	6144	7000	1/fosc	
PGOOD_ Lower Trip Threshold		With respect to error-compara threshold, hysteresis = 1% (ty		-12	-10	-8	%	
PGOOD_ Propagation Delay	tpgood_	Falling edge, 50mV overdrive Rising edge, 50mV overdrive			10 1		μs	
PGOOD_ Output Low Voltage		I <sub>SINK</sub> = 1mA				0.4	V	
PGOOD_ Leakage Current	IPGOOD_	High state, PGOOD_ forced to	5.5V			1	μΑ	
Thermal-Shutdown Threshold	tshdn	Hysteresis = 15°C			+160		°C	
GATE DRIVERS	-1	•		I.			I.	
DH_ Gate-Driver On-Resistance	R <sub>DH</sub>	BST LX_ forced to 5V			1.3	5	Ω	
	-	DL_, high state			1.7	5		
DL_ Gate-Driver On-Resistance	R <sub>DL</sub>	DL_, low state			0.6 3		Ω	
DH_ Gate-Driver Source/Sink Current	I <sub>DH</sub>	DH_ forced to 2.5V, BST LX 5V	X_ forced to		2		А	
DL_ Gate-Driver Source Current	I <sub>DL</sub>	DL_ forced to 2.5V			1.7		А	
DL_ Gate-Driver Sink Current	IDL (SINK)	DL_ forced to 2.5V			3.3		А	
Dead Time		DH_low to DL_high		15	45			
Dead Time	†DEAD	DL_low to DH_high		15	44		ns	
Internal BST_ Switch On-Resistance	R <sub>BST</sub>	I <sub>BST</sub> = 10mA			5		Ω	
BST_ Leakage Current		V <sub>BST</sub> _ = 26V			2	20	μΑ	
INPUTS AND OUTPUTS				•			•	
OUDS.		Rising trip level		1.1	1.6	2.2		
SHDN Input Trip Level		Falling trip level		0.96	1	1.04	V	
ONIA I - siis Issaat Valta			High	2.4				
ONA Logic Input Voltage		Hysteresis = 600mV (typ)	Low			0.8	V	
		SMPS off level/clear fault leve				0.8	V	
ON3, ON5 Input Voltage		Delay start level		1.9		2.1		
. •		SMPS on level		2.4				

## **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5, I<sub>REF</sub> = I<sub>LDO5</sub> = I<sub>OUTA</sub> = no load, **T<sub>A</sub>** = **0°C** to **+85°C**, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Tri I and I and I aria		0/10 5051	High	V <sub>LDO5</sub> - 0.4			V
Tri-Level Input Logic	,	SKIP, FSEL	REF	1.65		2.35	V
			GND			0.5	
Input Lookaga Current		SKIP, FSEL forced to GND or	LDO5	-1		+1	^
Input Leakage Current		SHDN forced to GND or 26V		-1		+1	μΑ

## **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1,  $V_{IN}$  = 12V, both SMPS enabled, FSEL = REF,  $\overline{SKIP}$  = GND, ILIM = LDO5, FBA = LDO5, I<sub>REF</sub> = I<sub>LDO5</sub> = I<sub>OUTA</sub> = no load,  $T_A$  = -40°C to +85°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS
INPUT SUPPLIES (Note 1)					
V <sub>IN</sub> Input Voltage Range	VIN	LDO5 in regulation	5.4	26.0	V
VIN Input Voltage hange	VIN	IN = LDO5, V <sub>CSL5</sub> < 4.4V	4.5	5.5	V
V <sub>IN</sub> Operating Supply Current	I <sub>IN</sub>	LDO5 switched over to CSL5, either SMPS on		40	μΑ
V <sub>IN</sub> Standby Supply Current	I <sub>IN(STBY)</sub>	$V_{IN}$ = 6V to 26V, both SMPS off, includes $ SHDN $		120	μA
V <sub>IN</sub> Shutdown Supply Current	IN(SHDN)	V <sub>IN</sub> = 6V to 26V		20	μΑ
Quiescent Power Consumption	PQ	Both SMPS on, FB3 = FB5 = LDO5; SKIP = GND, VCSL3 = 3.5V, VCSL5 = 5.3V, VOUTA = 15V, PIN + PCSL3 + PCSL5 + POUTA		4.5	mW
MAIN SMPS CONTROLLERS					
3.3V Output Voltage in Fixed Mode	V <sub>OUT3</sub>	$V_{IN} = 6V$ to 26V, $\overline{SKIP} = FB3 = LDO5$ , $0 < V_{CSH3} - V_{CSL3} < 50mV$ (Note 2)	3.255	3.375	V
5V Output Voltage in Fixed Mode	V <sub>OUT5</sub>	V <sub>IN</sub> = 6V to 26V, <del>SKIP</del> = FB5 = LDO5, 0 < V <sub>CSH5</sub> - V <sub>CSL5</sub> < 50mV (Note 2)	4.925	5.105	V
Feedback Voltage in Adjustable Mode	V <sub>FB</sub> _	V <sub>IN</sub> = 6V to 26V, FB3 or FB5 duty factor = 20% to 80% (Note 2)	1.974	2.046	V
Output Voltage Adjust Range		Either SMPS	2.0	5.5	V
FB3, FB5 Dual Mode Threshold			3V	V <sub>LDO5</sub> - 0.4	V
		FSEL = GND	170	230	
Operating Frequency (Note 1)	fosc	FSEL = REF	270	330	kHz
		FSEL = LDO5	425	575	
Maximum Duty Factor	DMAX		97		%

## **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1, V<sub>IN</sub> = 12V, both SMPS enabled, FSEL = REF, SKIP = GND, ILIM = LDO5, FBA = LDO5, I<sub>REF</sub> = I<sub>LDO5</sub> = I<sub>OUTA</sub> = no load, **T<sub>A</sub> = -40°C to +85°C**, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	MAX	UNITS
CURRENT LIMIT				•		
ILIM Adjustment Range				0.5	V <sub>REF</sub>	V
Current-Limit Threshold (Fixed)	V <sub>LIMIT</sub>	V <sub>CSH</sub> - V <sub>CSL</sub> , ILIM	= LDO5	44	56	mV
Current-Limit Threshold	VLIMIT	Vcsh Vcsl_	V <sub>ILIM</sub> = 2.00V	185	215	mV
(Adjustable)	V LIIVII I	VCSH VCSL_	V <sub>ILIM</sub> = 1.00V	93	107	1110
INTERNAL FIXED LINEAR REGU	ILATORS					
LDO5 Output Voltage	V <sub>LDO5</sub>	ON5 = GND, 6V < V <sub>II</sub>	v < 26V,	4.85	5.10	V
LDO5 Undervoltage-Lockout Fault Threshold		Rising edge, hystere	Rising edge, hysteresis = 1% (typ)		4.1	V
LDO5 Bootstrap Switch		Rising edge of CSL5	, hysteresis = 1% (typ)	4.30	4.75	V
Short-Circuit Current		LDO5 = GND, ON5 =	GND		450	mA
Short-Circuit Current (Switched over to CSL5)		LDO5 = GND, V <sub>CSL5</sub>	> 4.7V	200		mA
<b>AUXILIARY LINEAR REGULATO</b>	R	,		•		
DRVA Voltage Range	V <sub>DRVA</sub>			0.5	26.0	V
DRVA Drive Current		V <sub>FBA</sub> = 1.05V, V <sub>DRVA</sub> = 5V			0.4	mA
DRVA Drive Current		V <sub>FBA</sub> = 0.965V, V <sub>DRV</sub>	V <sub>FBA</sub> = 0.965V, V <sub>DRVA</sub> = 5V			] IIIA
FBA Regulation Threshold	V <sub>FBA</sub>	V <sub>DRVA</sub> = 5V, I <sub>DRVA</sub> = 1mA (sink)		0.98	1.02	V
OUTA Shunt Trip Level				25	27	V
REFERENCE (REF)						
Reference Voltage	VREF	LDO5 in regulation, I	REF = 0	1.980	2.020	V

## **ELECTRICAL CHARACTERISTICS (continued)**

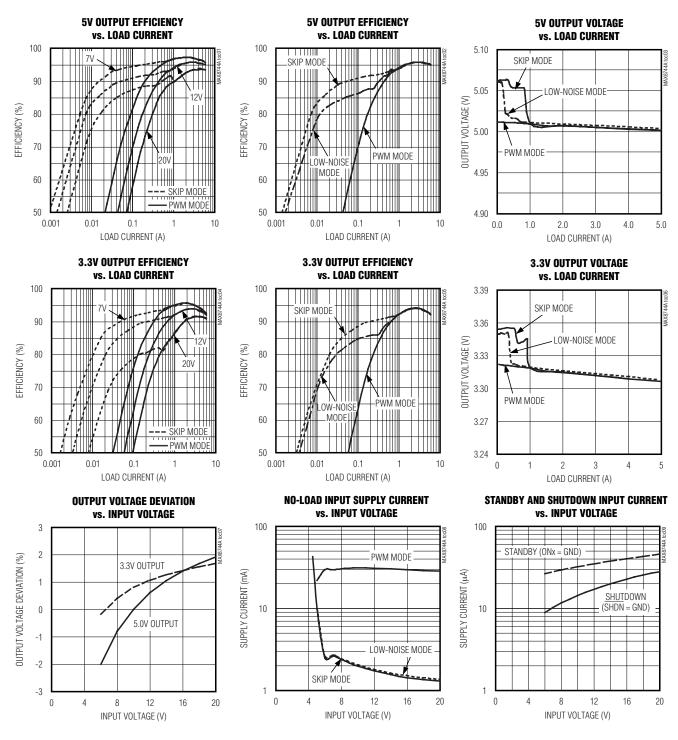
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PARAMETER	SYMBOL	CONDITIONS	MIN TY	/P MAX	UNITS	
FAULT DETECTION	1			•		•
Output Overvoltage Trip Threshold (MAX8744A Only)		With respect to error compara	tor threshold	8	14	%
Output Undervoltage Protection		With respect to error compara	tor threshold	65	75	%
PGOOD_ Lower Trip Threshold		With respect to error compara hysteresis = 1%	itor threshold,	-12	-8	%
PGOOD_ Output Low Voltage		I <sub>SINK</sub> = 1mA			0.4	V
GATE DRIVERS						
DH_ Gate-Driver On-Resistance	R <sub>DH</sub>	BST LX_ forced to 5V			5	Ω
DL_ Gate-Driver On-Resistance	Poi	DL_, high state DL_, low state			5	Ω
DL_ Gate-Driver Ori-nesistance	R <sub>DL</sub>				3	22
INPUTS AND OUTPUTS						
SHDN Input Trip Level		Rising trip level		1.0	2.3	
Short input trip Level		Falling trip level		0.96	1.04	
ONIA Logio Input Voltago		Hyptorogia - 600mV	High	2.4		V
ONA Logic Input Voltage		Hysteresis = 600mV	Low		0.8	V
		SMPS off level/clear fault level	I		0.8	
ON3, ON5 Input Voltage		Delay start level		1.9	2.1	V
		SMPS on level		2.4		
			High	V <sub>LDO5</sub> - 0.4		
Tri-Level Input Logic		SKIP, FSEL		1.65	2.35	V
			GND		0.5	

- Note 1: The MAX8744A/MAX8745A cannot operate over all combinations of frequency, input voltage (V<sub>IN</sub>), and output voltage. For large input-to-output differentials and high switching-frequency settings, the required on-time may be too short to maintain the regulation specifications. Under these conditions, a lower operating frequency must be selected. The minimum on-time must be greater than 150ns, regardless of the selected switching frequency. On-time and off-time specifications are measured from 50% point to 50% point at the DH\_ pin with LX\_ = GND, VBST\_ = 5V, and a 250pF capacitor connected from DH\_ to LX\_. Actual in-circuit times may differ due to MOSFET switching speeds.
- Note 2: When the inductor is in continuous conduction, the output voltage has a DC-regulation level lower than the error-comparator threshold by 50% of the ripple. In discontinuous conduction (SKIP = GND, light load), the output voltage has a DC regulation level higher than the trip level by approximately 1.1% due to slope compensation.
- Note 3: Specifications from -40°C to +85°C are guaranteed by design, not production tested.

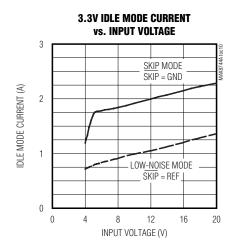
## **Typical Operating Characteristics**

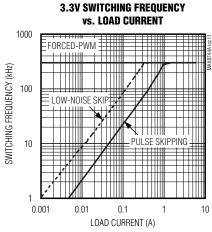
(Circuit of Figure 1,  $V_{IN} = 12V$ ,  $\overline{SKIP} = GND$ , FSEL = REF,  $T_A = +25^{\circ}C$ , unless otherwise noted.)

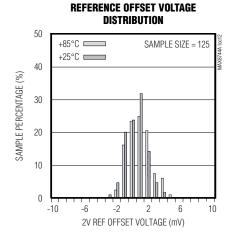


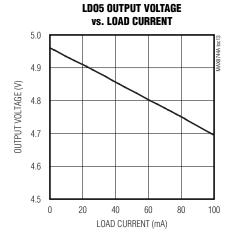
## Typical Operating Characteristics (continued)

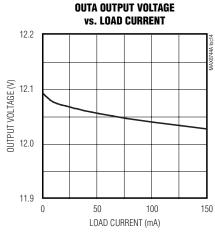
(Circuit of Figure 1,  $V_{IN} = 12V$ ,  $\overline{SKIP} = GND$ , FSEL = REF,  $T_A = +25^{\circ}C$ , unless otherwise noted.)

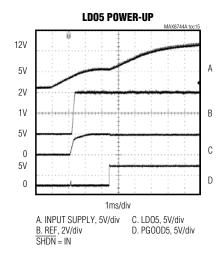






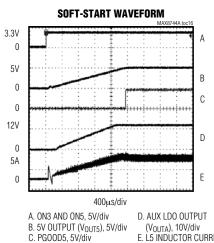




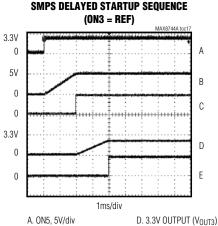


## Typical Operating Characteristics (continued)

(Circuit of Figure 1, V<sub>IN</sub> = 12V, SKIP = GND, FSEL = REF, T<sub>A</sub> = +25°C, unless otherwise noted.)



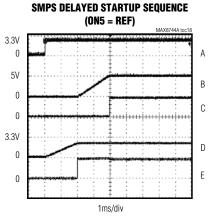




5V/div

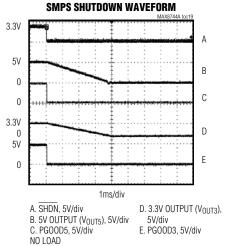
E. PG00D3, 5V/div

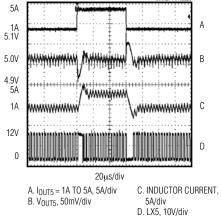
A. ON5, 5V/div B. 5V OUTPUT (V<sub>OUT5</sub>), 5V/div C. PGOOD5, 5V/div ON3 = REF



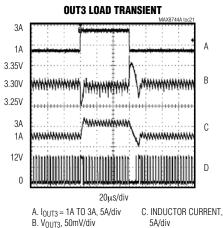
A. ON3, 5V/div B. 5V OUTPUT (V<sub>OUT5</sub>), 5V/div C. PGOOD5, 5V/div ON5 = REF

D. 3.3V OUTPUT (V<sub>OUT3</sub>) 5V/div E. PGOOD3, 5V/div





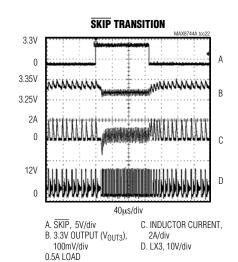
**OUT5 LOAD TRANSIENT** 

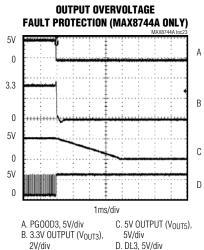


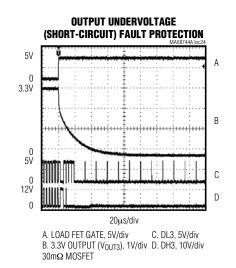
D. LX3, 10V/div

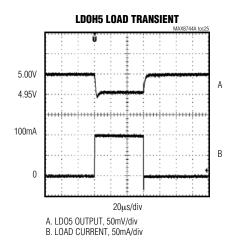
## Typical Operating Characteristics (continued)

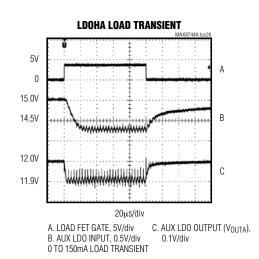
(Circuit of Figure 1,  $V_{IN} = 12V$ ,  $\overline{SKIP} = GND$ , FSEL = REF,  $T_A = +25^{\circ}C$ , unless otherwise noted.)











## **Pin Description**

PIN	NAME	FUNCTION
1	ONA	Auxiliary LDO Enable Input. When ONA is pulled low, OUTA is high impedance and the secondary feedback control is disabled. When ONA is driven high, the controller enables the auxiliary LDO.
2	DRVA	Auxiliary LDO Transistor Base Driver. Connect DRVA to the base of a pnp power transistor. Add a $680\Omega$ pullup resistor between the base and emitter.
3	ILIM	Peak Current-Limit Threshold Adjustment. The current-limit threshold defaults to 50mV if ILIM is pulled up to LDO5. In adjustable mode, the current-limit threshold across CSH_ and CSL_ is precisely 1/10 the voltage seen at ILIM over a 0.5V to 2.0V range. The logic threshold for switchover to the 50mV default value is approximately VLDO5 - 1V.
4	SHDN	Shutdown Control Input. The device enters its 8µA supply-current shutdown mode if V SHDN is less than the SHDN input falling edge trip level and does not restart until V SHDN is greater than the SHDN input rising-edge trip level. Connect SHDN to V <sub>IN</sub> for automatic startup. SHDN can be connected to V <sub>IN</sub> through a resistive voltage-divider to implement a programmable undervoltage lockout.
5	ON3	3.3V SMPS Enable Input. Driving ON3 high enables the 3.3V SMPS, while pulling ON3 low disables the 3.3V SMPS. If ON3 is connected to REF, the 3.3V SMPS starts after the 5V SMPS reaches regulation (delayed start). Drive ON3 below the clear fault level to reset the fault latch.
6	ON5	5V SMPS Enable Input. Driving ON5 high enables the 5V SMPS, while pulling ON5 low disables the 5V SMPS. If ON5 is connected to REF, the 5V SMPS starts after the 3.3V SMPS reaches regulation (delayed start). Drive ON5 below the clear fault level to reset the fault latch.
7	REF	2.0V Reference Voltage Output. Bypass REF to analog ground with a 0.1µF or greater ceramic capacitor. The reference sources up to 50µA for external loads. Loading REF degrades output-voltage accuracy according to the REF load-regulation error. The reference shuts down when the system pulls \$\overline{SHDN}\$ low.
8	GND	Analog Ground. Connect the exposed backside pad to GND.
9	FSEL	Frequency Select Input. This three-level logic input sets the controllers' switching frequency. Connect to LDO5, REF, or GND to select the following typical switching frequencies: LDO5 = 500kHz, REF = 300kHz, GND = 200kHz.
10	SKIP	Pulse-Skipping Control Input. Connect to LDO5 for low-noise, forced-PWM operation. Connect to REF for automatic, low-noise, pulse-skipping operation at light loads. Connect to GND for automatic, higherfliciency, pulse-skipping operation at light loads.
11	FB5	Feedback Input for the 5V SMPS. Connect to LDO5 for the preset 5V output. In adjustable mode, FB5 regulates to 2V.
12	CSH5	Positive Current-Sense Input for the 5V SMPS. Connect to the positive terminal of the current-sense element. Figure 7 describes two different current-sensing options—using accurate sense resistors or lossless inductor DCR sensing.
13	CSL5	Output-Sense and Negative Current-Sense Input for the 5V SMPS. When using the internal preset 5V feedback-divider (FB5 = LDO5), the controller uses CSL5 to sense the output voltage. Connect to the negative terminal of the current-sense element. CSL5 also serves as the bootstrap input for LDO5.
14	PGOOD5	Open-Drain, Power-Good Output for the 5V SMPS. PGOOD5 is pulled low if CSL5 drops more than 10% (typ) below the normal regulation point. PGOOD5 is held low during soft-start and shutdown. PGOOD5 becomes high impedance when CSL5 is in regulation.

## Pin Description (continued)

PIN	NAME	FUNCTION
15	BST5	Boost Flying Capacitor Connection for the 5V SMPS. The MAX8744A/MAX8745A include an internal boost switch connected between LDO5 and BST5. Connect to an external capacitor as shown in Figure 1.
16	DH5	High-Side Gate-Driver Output for the 5V SMPS. DH5 swings from LX5 to BST5.
17	LX5	Inductor Connection for the 5V SMPS. Connect LX5 to the switched side of the inductor. LX5 serves as the lower supply rail for the DH5 high-side gate driver.
18	DL5	Low-Side Gate-Driver Output for the 5V SMPS. DL5 swings from PGND to LDO5.
19	PGND	Power Ground
20	LDO5	5V Internal Linear-Regulator Output. Bypass with 4.7μF minimum (1μF/25mA). Provides at least 100mA for the DL_ low-side gate drivers, the DH_ high-side drivers through the BST switches, the PWM controller, logic, reference, and external loads. If CSL5 is greater than 4.5V and soft-start is complete, the linear regulator shuts down, and LDO5 connects to CSL5 through a 1Ω switch rated for loads up to 200mA.
21	IN	Input of the Startup Circuitry and the LDO5 Internal 5V Linear Regulator. Bypass to PGND with a 0.22µF or greater ceramic capacitor close to the IC.
22	PGOODA	Open-Drain, Power-Good Output for the Auxiliary LDO. PGOODA is pulled low if FBA drops more than 10% (typ) below the normal regulation point, and when the auxiliary LDO is shut down. PGOODA becomes high impedance when FBA is in regulation.
23	DL3	Low-Side Gate-Driver Output for the 3.3V SMPS. DL3 swings from PGND to LDO5.
24	LX3	Inductor Connection for the 3.3V SMPS. Connect LX3 to the switched side of the inductor. LX3 serves as the lower supply rail for the DH3 high-side gate driver.
25	DH3	High-Side Gate-Driver Output for the 3.3V SMPS. DH3 swings from LX3 to BST3.
26	BST3	Boost Flying Capacitor Connection for the 3.3V SMPS. The MAX8744A/MAX8745A include an internal boost switch connected between LDO5 and BST3. Connect to an external capacitor as shown in Figure 1.
27	PGOOD3	Open-Drain, Power-Good Output for the 3.3V SMPS. PGOOD3 is pulled low if CSL3 drops more than 10% (typ) below the normal regulation point. PGOOD3 is held low during soft-start and shutdown. PGOOD3 becomes high impedance when CSL3 is in regulation.
28	CSL3	Output Sense and Negative Current Sense for the 3.3V SMPS. When using the internal preset 3.3V feedback divider (FB3 = LDO5), the controller uses CSL3 to sense the output voltage. Connect to the negative terminal of the current-sense element.
29	CSH3	Positive Current-Sense Input for the 3.3V SMPS. Connect to the positive terminal of the current-sense element. Figure 7 describes two different current-sensing options—using accurate sense resistors or lossless inductor DCR sensing.
30	FB3	Feedback Input for the 3.3V SMPS. Connect to LDO5 for fixed 3.3V output. In adjustable mode, FB3 regulates to 2V.
31	FBA	Auxiliary LDO Feedback Input. Connect a resistive voltage-divider from OUTA to analog ground to adjust the auxiliary linear-regulator output voltage. FBA regulates at 1V.

## Pin Description (continued)

PIN	NAME	FUNCTION
15	BST5	Boost Flying Capacitor Connection for the 5V SMPS. The MAX8744A/MAX8745A include an internal boost switch connected between LDO5 and BST5. Connect to an external capacitor as shown in Figure 1.
16	DH5	High-Side Gate-Driver Output for the 5V SMPS. DH5 swings from LX5 to BST5.
17	LX5	Inductor Connection for the 5V SMPS. Connect LX5 to the switched side of the inductor. LX5 serves as the lower supply rail for the DH5 high-side gate driver.
18	DL5	Low-Side Gate-Driver Output for the 5V SMPS. DL5 swings from PGND to LDO5.
19	PGND	Power Ground
20	LDO5	5V Internal Linear-Regulator Output. Bypass with 4.7 $\mu$ F minimum (1 $\mu$ F/25mA). Provides at least 100mA for the DL_ low-side gate drivers, the DH_ high-side drivers through the BST switches, the PWM controller, logic, reference, and external loads. If CSL5 is greater than 4.5V and soft-start is complete, the linear regulator shuts down, and LDO5 connects to CSL5 through a 1 $\Omega$ switch rated for loads up to 200mA.
21	IN	Input of the Startup Circuitry and the LDO5 Internal 5V Linear Regulator. Bypass to PGND with a 0.22µF or greater ceramic capacitor close to the IC.
22	PGOODA	Open-Drain, Power-Good Output for the Auxiliary LDO. PGOODA is pulled low if FBA drops more than 10% (typ) below the normal regulation point, and when the auxiliary LDO is shut down. PGOODA becomes high impedance when FBA is in regulation.
23	DL3	Low-Side Gate-Driver Output for the 3.3V SMPS. DL3 swings from PGND to LDO5.
24	LX3	Inductor Connection for the 3.3V SMPS. Connect LX3 to the switched side of the inductor. LX3 serves as the lower supply rail for the DH3 high-side gate driver.
25	DH3	High-Side Gate-Driver Output for the 3.3V SMPS. DH3 swings from LX3 to BST3.
26	BST3	Boost Flying Capacitor Connection for the 3.3V SMPS. The MAX8744A/MAX8745A include an internal boost switch connected between LDO5 and BST3. Connect to an external capacitor as shown in Figure 1.
27	PGOOD3	Open-Drain, Power-Good Output for the 3.3V SMPS. PGOOD3 is pulled low if CSL3 drops more than 10% (typ) below the normal regulation point. PGOOD3 is held low during soft-start and shutdown. PGOOD3 becomes high impedance when CSL3 is in regulation.
28	CSL3	Output Sense and Negative Current Sense for the 3.3V SMPS. When using the internal preset 3.3V feedback divider (FB3 = LDO5), the controller uses CSL3 to sense the output voltage. Connect to the negative terminal of the current-sense element.
29	CSH3	Positive Current-Sense Input for the 3.3V SMPS. Connect to the positive terminal of the current-sense element. Figure 7 describes two different current-sensing options—using accurate sense resistors or lossless inductor DCR sensing.
30	FB3	Feedback Input for the 3.3V SMPS. Connect to LDO5 for fixed 3.3V output. In adjustable mode, FB3 regulates to 2V.
31	FBA	Auxiliary LDO Feedback Input. Connect a resistive voltage-divider from OUTA to analog ground to adjust the auxiliary linear-regulator output voltage. FBA regulates at 1V.

N<sub>L3</sub> Low-Side MOSFET

Fairchild Semiconductor FDS6670S International Rectifier IRF7807VD1 Fairchild Semiconductor FDS6670S International Rectifier IRF7807VD1



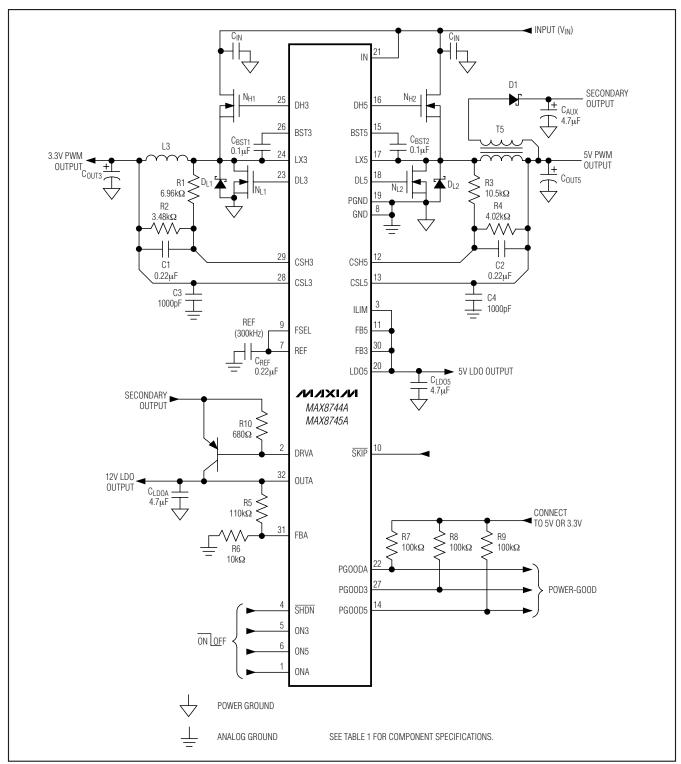


Figure 1. Standard Application Circuit

**Table 2. Component Suppliers** 

SUPPLIER	WEBSITE		
AVX	www.avx.com		
Central Semiconductor	www.centralsemi.com		
Fairchild	www.fairchildsemi.com		
International Rectifier	www.irf.com		
KEMET	www.kemet.com		
NEC/Tokin	www.nec-tokin.com		
Panasonic	www.panasonic.com/industrial		
Philips	www.philips.com		
Pulse	www.pulseeng.com		
Renesas	www.renesas.com		
SANYO	www.edc.sanyo.com		
Sumida	www.sumida.com		
Taiyo Yuden	www.t-yuden.com		
TDK	www.component.tdk.com		
TOKO	www.tokoam.com		
Vishay (Dale, Siliconix)	www.vishay.com		

## **Detailed Description**

The MAX8744A/MAX8745A standard application circuit (Figure 1) generates the 5V/5A and 3.3V/5A typical of the main supplies in a notebook computer. The input supply range is 7V to 24V. See Table 1 for component selections, while Table 2 lists the component manufacturers.

The MAX8744A/MAX8745A contain two interleaved, fixed-frequency, step-down controllers designed for low-voltage power supplies. The optimal interleaved architecture guarantees out-of-phase operation, reducing the input capacitor ripple. One internal LDO generates the keep-alive 5V power. The MAX8744A/MAX8745A have an auxiliary LDO with an adjustable output for generating either the 3.3V keep-alive supply or regulating the low-power 12V system supply.

#### Fixed 5V Linear Regulator (LDO5)

An internal linear regulator produces a preset 5V low-current output. LDO5 powers the gate drivers for the external MOSFETs, and provides the bias supply required for the SMPS analog controller, reference, and logic blocks. LDO5 supplies at least 100mA for external and internal loads, including the MOSFET gate drive, which typically varies from 5mA to 50mA, depending on the switching frequency and external MOSFETs selected. Bypass LDO5 with a 4.7µF or greater ceramic capacitor (1µF per 25mA of load) to guarantee stability under the full-load conditions.

The MAX8744A/MAX8745A switch-mode power supplies (SMPS) require a 5V bias supply in addition to the high-power input supply (battery or AC adapter). This 5V bias supply is generated by the controller's internal 5V linear regulator (LDO5). This bootstrapped LDO allows the controller to power up independently. The gate-driver input supply is connected to the fixed 5V linear-regulator output (LDO5). Therefore, the 5V LDO supply must provide LDO5 (PWM controller) and the gate-drive power, so the maximum supply current required is:

IBIAS = ICC + fSW (QG(LOW) + QG(HIGH))= 5mA to 50mA (typ)

where  $I_{CC}$  is 0.7mA (typ),  $f_{SW}$  is the switching frequency, and  $Q_{G(LOW)}$  and  $Q_{G(HIGH)}$  are the MOSFET data sheet's total gate-charge specification limits at  $V_{GS} = 5V$ .

#### SMPS to LDO Bootstrap Switchover

When the 5V main output voltage is above the LDO5 bootstrap-switchover threshold and has completed soft-start, an internal  $1\Omega$  (typ) p-channel MOSFET shorts CSL5 to LDO5, while simultaneously shutting down the LDO5 linear regulator. This bootstraps the device, powering the internal circuitry and external loads from the 5V SMPS output (CSL5), rather than through the linear regulator from the battery. Bootstrapping reduces power dissipation due to gate charge and quiescent losses by providing power from a 90%-efficient switch-mode source, rather than from a much-less-efficient linear regulator. The current capability increases from 100mA to 200mA when the LDO5 output is switched over to CSL5. When ON5 is pulled low, the controller immediately disables the bootstrap switch and reenables the 5V LDO.

#### Reference (REF)

The 2V reference is accurate to  $\pm 1\%$  over temperature and load, making REF useful as a precision system reference. Bypass REF to GND with a  $0.1\mu F$  or greater ceramic capacitor. The reference sources up to  $50\mu A$  and sinks  $5\mu A$  to support external loads. If highly accurate specifications are required for the main SMPS output voltages, the reference should not be loaded. Loading the reference reduces the LDO5, CSL5 (OUT5), CSL3 (OUT3), and OUTA output voltages slightly because of the reference load-regulation error.

#### System Enable/Shutdown (SHDN)

Drive SHDN below the precise SHDN input falling-edge trip level to place the MAX8744A/MAX8745A in its low-power shutdown state. The controller consumes only 8µA of quiescent current while in shutdown mode. When shutdown mode activates, the reference turns off after the controller completes the shutdown sequence

making the threshold to exit shutdown less accurate. To guarantee startup, drive SHDN above 2V (SHDN input rising-edge trip level). For automatic shutdown and startup, connect SHDN to VIN. The accurate 1V falling-edge threshold on SHDN can be used to detect a specific input voltage level and shut the device down. Once in shutdown, the 1.6V rising-edge threshold activates, providing sufficient hysteresis for most applications.

### SMPS POR, UVLO, and Soft-Start

Power-on reset (POR) occurs when LDO5 rises above approximately 1V, resetting the undervoltage, overvoltage, and thermal-shutdown fault latches. The POR circuit also ensures that the low-side drivers are pulled high until the SMPS controllers are activated. Figure 2 is the MAX8744A/MAX8745A block diagram.

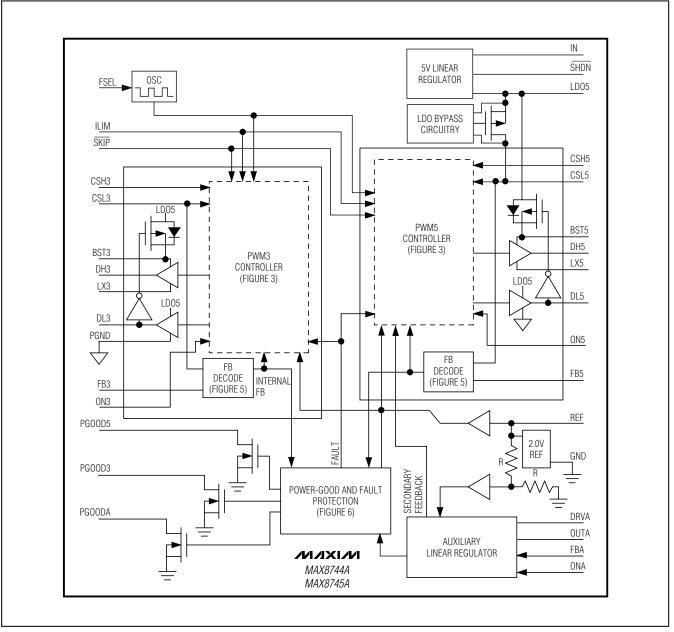


Figure 2. Block Diagram

/U/IXI/U

**Table 3. Operating Mode Truth Table** 

MODE		INPUTS*		OUTPUTS				
MODE	SHDN ON5		ON3	LDO5	5V SMPS	3V SMPS		
Shutdown Mode	Low	Х	Х	OFF	OFF	OFF		
Standby Mode	High	Low	Low	ON	OFF	OFF		
Normal Operation	High	High	High	ON	ON	ON		
3.3V SMPS Active	High	Low	High	ON	OFF	ON		
5V SMPS Active	High	High	Low	OFF LDO5 to CSL5 bypass switch enabled	ON	OFF		
Normal Operation (Delayed 5V SMPS Startup)	High	Ref	High	OFF LDO5 to CSL5 bypass switch enabled	ON Power-up after 3.3V SMPS is in regulation	ON		
Normal Operation (Delayed 3.3V SMPS Startup)	High	High	Ref	OFF LDO5 to CSL5 bypass switch enabled	ON	ON Power-up after 5V SMPS is in regulation		

<sup>\*</sup>SHDN is an accurate, low-voltage logic input with 1V falling-edge threshold voltage and 1.6V rising-edge threshold voltage. ON3 and ON5 are tri-level CMOS logic inputs, a logic-low voltage is less than 0.8V, a logic-high voltage is greater than 2.4V, and the mid-dle-logic level is between 1.7V and 2.3V (see the Electrical Characteristics table).

The LDO5 input undervoltage-lockout (UVLO) circuitry inhibits switching if the 5V bias supply (LDO5) is below its 4V UVLO threshold. Once the 5V bias supply (LDO5) rises above this input UVLO threshold and the SMPS controllers are enabled (ON\_ driven high), the SMPS controllers start switching, and the output voltages begin to ramp up using soft-start. If the LDO5 voltage drops below the UVLO threshold, the controller stops switching and pulls the low-side gate drivers low until the LDO5 voltage recovers or drops below the POR threshold.

The internal soft-start gradually increases the feedback voltage with a 1V/ms slew rate. Therefore, the outputs reach their nominal regulation voltage 2ms after the SMPS controllers are enabled (see the SMPS Shutdown Waveform in the *Typical Operating Characteristics*). This gradual slew rate effectively reduces the input surge current by minimizing the current required to charge the output capacitors (IOUT = ILOAD + COUT x VOUT(NOM) / tSLEW).

#### SMPS Enable Controls (ON3, ON5)

ON3 and ON5 control SMPS power-up sequencing. ON3 or ON5 rising above 2.4V enables the respective outputs. ON3 or ON5 falling below 1.6V disables the respective outputs. Driving ON\_ below 0.8V clears the overvoltage, undervoltage, and thermal fault latches.

### SMPS Power-Up Sequencing

Connecting ON3 or ON5 to REF forces the respective outputs off while the other output is below regulation and starts after that output regulates. The second SMPS remains on until the first SMPS turns off, the device shuts down, a fault occurs, or LDO5 goes into UVLO. Both supplies begin their power-down sequence immediately when the first supply turns off.

#### Output Discharge (Soft-Shutdown)

When the switching regulators are disabled—when ON\_ or SHDN is pulled low, or when an output undervoltage fault occurs—the internal soft-shutdown gradually decreases the feedback voltage with a 0.5V/ms slew rate. Therefore, the regulation voltage drops to 0V within 4ms after the SMPS controllers are disabled (see the SMPS Shutdown Waveform in the Typical Operating Characteristics). This slowly discharges the output capacitance, eliminating the negative output voltages caused by quickly discharging the output through the inductor and low-side MOSFET. When an SMPS target voltage discharges to 0.1V, its low-side driver (DL\_) is forced high, clamping the respective SMPS output to GND. The reference remains active to provide an accurate threshold and to provide overvoltage protection. Both SMPS controllers contain separate soft-shutdown circuits.

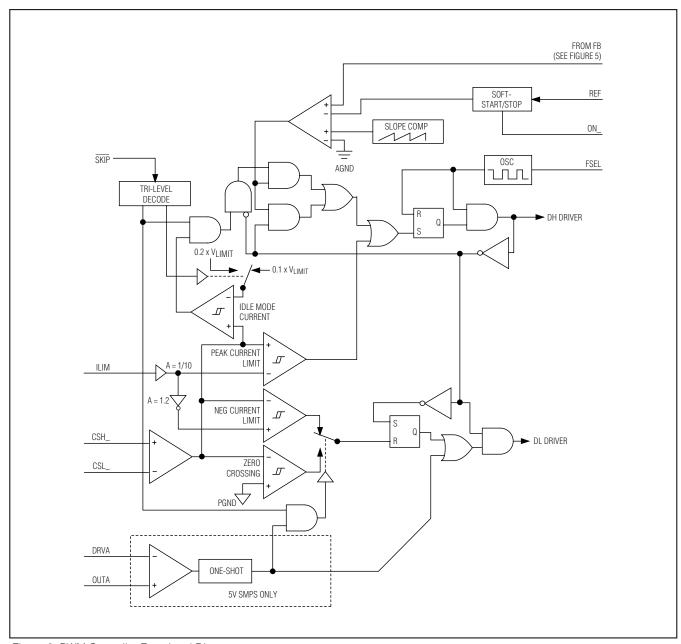


Figure 3. PWM Controller Functional Diagram

# Fixed-Frequency, Current-Mode PWM Controller

The heart of each current-mode PWM controller is a multi-input, open-loop comparator that sums two signals: the output-voltage error signal with respect to the

reference voltage and the slope-compensation ramp (Figure 3). The MAX8744A/MAX8745A use a direct-summing configuration, approaching ideal cycle-to-cycle control over the output voltage without a traditional error amplifier and the phase shift associated with it.

**Table 4. FSEL Configuration Table** 

FSEL	SWITCHING FREQUENCY (kHz)
LDO5	500
REF	300
GND	200

### Frequency Selection (FSEL)

The FSEL input selects the PWM mode switching frequency. Table 4 shows the switching frequency based on FSEL connection. High-frequency (500kHz) operation optimizes the application for the smallest component size, trading off efficiency due to higher switching losses. This may be acceptable in ultraportable devices where the load currents are lower. Low-frequency (200kHz) operation offers the best overall efficiency at the expense of component size and board space.

#### **Forced-PWM Mode**

The low-noise forced-PWM mode (SKIP = LDO5) disables the zero-crossing comparator, which controls the low-side switch on-time. This forces the low-side gate-drive waveform to be constantly the complement of the high-side gate-drive waveform, so the inductor current reverses at light loads while DH\_ maintains a duty factor of Vout/VIN. The benefit of forced-PWM mode is to keep the switching frequency fairly constant. However, forced-PWM operation comes at a cost: the no-load 5V supply current remains between 20mA to 50mA, depending on the external MOSFETs and switching frequency.

Forced-PWM mode is most useful for avoiding audiofrequency noise and improving load-transient response. Since forced-PWM operation disables the zero-crossing comparator, the inductor current reverses under light loads.

#### **Light-Load Operation Control (SKIP)**

The MAX8744A/MAX8745A include a light-load operating mode control input (SKIP) used to enable or disable the zero-crossing comparator for both switching regulators. When the zero-crossing comparator is enabled, the regulator forces DL\_ low when the current-sense inputs detect zero inductor current. This keeps the inductor from discharging the output capacitors and forces the regulator to skip pulses under light-load conditions to avoid overcharging the output. When the zero-crossing comparator is disabled, the regulator is forced to maintain PWM operation under light-load conditions (forced PWM).

#### Idle Mode Current-Sense Threshold

When pulse-skipping mode is enabled, the on-time of the step-down controller terminates when the output voltage exceeds the feedback threshold and when the currentsense voltage exceeds the idle mode current-sense threshold. Under light-load conditions, the on-time duration depends solely on the idle mode current-sense threshold, which is 20% ( $\overline{SKIP} = GND$ ) of the full-load current-limit threshold set by ILIM, or the low-noise current-sense threshold, which is 10% ( $\overline{SKIP} = REF$ ) of the full-load current-limit threshold set by ILIM. This forces the controller to source a minimum amount of power with each cycle. To avoid overcharging the output, another on-time cannot begin until the output voltage drops below the feedback threshold. Since the zero-crossing comparator prevents the switching regulator from sinking current, the controller must skip pulses. Therefore, the controller regulates the valley of the output ripple under light-load conditions.

### Automatic Pulse-Skipping Crossover

In skip mode, an inherent automatic switchover to PFM takes place at light loads (Figure 4). This switchover is affected by a comparator that truncates the low-side switch on-time at the inductor current's zero crossing. The zero-crossing comparator senses the inductor current across CSH\_ to CSL\_. Once VCSH\_ - VCSL\_ drops below the 3mV zero-crossing, current-sense threshold, the comparator forces DL\_ low (Figure 3). This mechanism causes the threshold between pulse-skipping PFM and nonskipping PWM operation to coincide with the boundary between continuous and discontinuous inductor-current operation (also known as the "critical conduction" point). The load-current level at which PFM/PWM crossover occurs, ILOAD(SKIP), is given by:

$$I_{LOAD(SKIP)} = \frac{(V_{IN} - V_{OUT})V_{OUT}}{2V_{IN}I_{OSC}L}$$

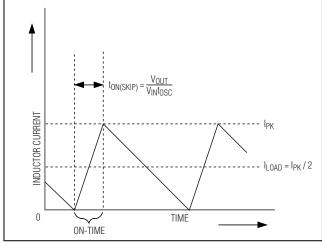


Figure 4. Pulse-Skipping/Discontinuous Crossover Point

The switching waveforms may appear noisy and asynchronous when light loading causes pulse-skipping operation, but this is a normal operating condition that results in high light-load efficiency. Trade-offs in PFM noise vs. light-load efficiency are made by varying the inductor value. Generally, low inductor values produce a broader efficiency vs. load curve, while higher values result in higher full-load efficiency (assuming that the coil resistance remains fixed) and less output-voltage ripple. Penalties for using higher inductor values include larger physical size and degraded load-transient response (especially at low input-voltage levels).

### **Output Voltage**

DC output accuracy specifications in the *Electrical Characteristics* table refer to the error comparator's threshold. When the inductor continuously conducts, the MAX8744A/MAX8745A regulate the peak of the output ripple, so the actual DC output voltage is lower than the slope-compensated trip level by 50% of the output ripple voltage. For PWM operation (continuous conduction), the output voltage is accurately defined by the following equation:

$$V_{OUT(PWM)} = V_{NOM} \left(1 - \frac{A_{SLOPE}V_{RIPPLE}}{V_{IN}}\right) - \left(\frac{V_{RIPPLE}}{2}\right)$$

where  $V_{NOM}$  is the nominal output voltage,  $A_{SLOPE}$  equals 1.1%, and  $V_{RIPPLE}$  is the output ripple voltage ( $V_{RIPPLE} = ESR \times \Delta I_{INDUCTOR}$ , as described in the *Output Capacitor Selection* section).

In discontinuous conduction (I<sub>OUT</sub> < I<sub>LOAD(SKIP)</sub>), the MAX8744A/MAX8745A regulate the valley of the output ripple, so the output voltage has a DC regulation level higher than the error-comparator threshold. For PFM operation (discontinuous conduction), the output voltage is approximately defined by the following equation:

$$V_{OUT(PFM)} = V_{NOM} + \frac{1}{2} \left( \frac{f_{SW}}{f_{OSC}} \right) I_{IDLE}ESR$$

where  $V_{NOM}$  is the nominal output voltage, fosc is the maximum switching frequency set by the internal oscillator, fsw is the actual switching frequency, and  $I_{IDLE}$  is the idle mode inductor current when pulse skipping.

Connect FB3 and FB5 to LDO5 to enable the fixed SMPS output voltages (3.3V and 5V, respectively), set by a preset, internal resistive voltage-divider connected between the output (CSL\_) and analog ground. Connect a resistive voltage-divider at FB\_ between the output (CSL\_) and GND to adjust the respective output voltage between 2V and 5.5V (Figure 5). Choose RFBLO (resistance from FB to AGND) to be approximately

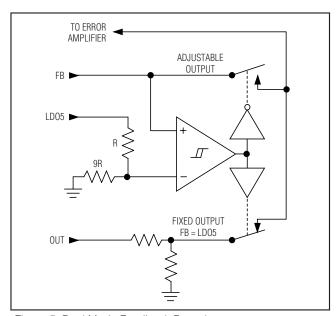


Figure 5. Dual Mode Feedback Decoder

 $10k\Omega$  and solve for R<sub>FBHI</sub> (resistance from the output to FB) using the equation:

$$R_{FBHI} = R_{FBLO} \left( \frac{V_{OUT}}{V_{FB}} - 1 \right)$$

where  $V_{FB} = 2V$  nominal.

When adjusting both output voltages, set the 3.3V SMPS lower than the 5V SMPS. LDO5 connects to the 5V output (CSL5) through an internal switch only when CSL5 is above the LDO5 bootstrap threshold (4.5V) and the soft-start sequence for the CSL5 side has completed. Bootstrapping works most effectively when the fixed output voltages are used. Once LDO5 is bootstrapped from CSL5, the internal 5V linear regulator turns off. This reduces the internal power dissipation and improves efficiency at higher input voltages.

#### **Current-Limit Protection (ILIM)**

The current-limit circuit uses differential current-sense inputs (CSH\_ and CSL\_) to limit the peak inductor current. If the magnitude of the current-sense signal exceeds the current-limit threshold, the PWM controller turns off the high-side MOSFET (Figure 3). The actual maximum load current is less than the peak current-limit threshold by an amount equal to half of the inductor ripple current. Therefore, the maximum load capability is a function of the current-sense resistance, inductor value, switching frequency, and duty cycle (VOUT/VIN).

MIXIM

In forced-PWM mode, the MAX8744A/MAX8745A also implement a negative current limit to prevent excessive reverse inductor currents when V<sub>OUT</sub> is sinking current. The negative current-limit threshold is set to approximately 120% of the positive current limit and tracks the positive current limit when ILIM is adjusted.

Connect ILIM to LDO5 for the 50mV default threshold, or adjust the current-limit threshold with an external resistor-divider at ILIM. Use a 2 $\mu A$  to 20 $\mu A$  divider current for accuracy and noise immunity. The current-limit threshold adjustment range is from 50mV to 200mV. In the adjustable mode, the current-limit threshold voltage equals precisely 1/10 the voltage seen at ILIM. The logic threshold for switchover to the default value is approximately  $V_{\rm LDO5}$  - 1V.

Carefully observe the PCB layout guidelines to ensure that noise and DC errors do not corrupt the differential current-sense signals seen by CSH\_ and CSL\_. Place the IC close to the sense resistor with short, direct traces, making a Kelvin-sense connection to the current-sense resistor.

### **MOSFET Gate Drivers (DH\_, DL\_)**

The DH\_ and DL\_ drivers are optimized for driving moderate-sized high-side and larger low-side power MOSFETs. This is consistent with the low duty factor seen in notebook applications, where a large VIN - VOUT differential exists. The high-side gate drivers (DH\_) source and sink 2A, and the low-side gate drivers (DL\_) source 1.7A and sink 3.3A. This ensures robust gate drive for high-current applications. The DH\_ floating high-side MOSFET drivers are powered by charge pumps at BST\_ while the DL\_ synchronous-rectifier drivers are powered directly by the fixed 5V linear regulator (LDO5).

Adaptive dead-time circuits monitor the DL\_ and DH\_ drivers and prevent either FET from turning on until the other is fully off. The adaptive driver dead-time allows operation without shoot-through with a wide range of MOSFETs, minimizing delays and maintaining efficiency. There must be a low-resistance, low-inductance path from the DL\_ and DH\_ drivers to the MOSFET gates for the adaptive dead-time circuits to work properly; otherwise, the sense circuitry in the MAX8744A/MAX8745A interprets the MOSFET gates as "off" while charge actually remains. Use very short, wide traces (50 mils to 100 mils wide if the MOSFET is 1in from the driver).

The internal pulldown transistor that drives DL\_ low is robust, with a  $0.6\Omega$  (typ) on-resistance. This helps prevent DL\_ from being pulled up due to capacitive coupling from the drain to the gate of the low-side MOSFETs when the inductor node (LX\_) quickly switches from ground to V<sub>IN</sub>.

Applications with high input voltages and long inductive driver traces may require additional gate-to-source capacitance to ensure fast-rising LX\_ edges do not pull up the low-side MOSFETs gate, causing shoot-through currents. The capacitive coupling between LX\_ and DL\_ created by the MOSFET's gate-to-drain capacitance (CGD = CRSS), gate-to-source capacitance (CGS = CISS - CGD), and additional board parasitics should not exceed the following minimum threshold:

$$V_{GS(TH)} > V_{IN} \left( \frac{C_{RSS}}{C_{ISS}} \right)$$

Lot-to-lot variation of the threshold voltage may cause problems in marginal designs.

### Power-Good Output (PGOOD\_)

PGOOD\_ is the open-drain output of a comparator that continuously monitors both SMPS output voltages and the auxiliary LDO output for undervoltage conditions. PGOOD\_ is actively held low in shutdown (\$\overline{S}HDN = GND), standby (\$ON3 = ON5 = ONA = GND), soft-start, and soft-shutdown. Once the soft-start sequence terminates, PGOOD\_ becomes high impedance as long as the outputs are above 90% of the nominal regulation voltage set by \$FB\_. PGOOD\_ goes low once the respective output drops 10% below its nominal regulation point, an SMPS output overvoltage fault occurs, or \$ON\_ or \$\overline{S}HDN\$ is low. For a logic-level PGOOD\_ output voltage, connect an external pullup resistor between PGOOD\_ and LDO5. A 100k\$\Overline{\Omega}\$ pullup resistor works well in most applications.

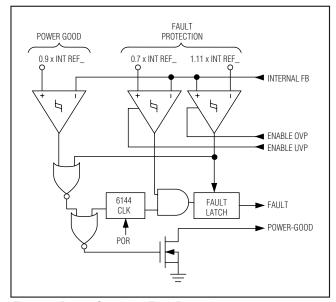


Figure 6. Power-Good and Fault Protection

## **Table 5. Operating Modes Truth Table**

MODE	CONDITION	COMMENT				
Power-Up	LDO5 < UVLO threshold	Transitions to discharge mode after V <sub>IN</sub> POR and after REF becomes valid. LDO5, REF remain active. DL_ is active (high).				
Run	SHDN = high, ON3 or ON5 enabled	Normal operation.				
Output Overvoltage (OVP) Protection (MAX8744A)	Either output > 111% of nominal level	Exited by POR or cycling SHDN, ON3, or ON5.				
Output Undervoltage Protection (UVP)	Either output < 70% of nominal level, UVP is enabled 6144 clock cycles (1 / fosc) after the output is enabled	Exited by POR or cycling SHDN, ON3, or ON5.				
Standby	ON5 and ON3 < startup threshold, SHDN = high	DL_ stays high. LDO5 active.				
Shutdown	SHDN = low	All circuitry off.				
Thermal Shutdown	T <sub>J</sub> > +160°C	Exited by POR or cycling SHDN, ON3, or ON5. DL3 and DL5 go high before LDO5 turns off. They remain high as long as possible thereafter.				
Switchover Fault	Excessive current on LDO5 switchover transistors	Exited by POR or cycling SHDN, ON3, or ON5.				

## Fault Protection

### Output Overvoltage Protection (OVP)— MAX8744A Only

If the output voltage of either SMPS rises above 111% of its nominal regulation voltage and the OVP protection is enabled, the controller sets the fault latch, pulls PGOOD low, shuts down the SMPS controllers that tripped the fault, and immediately pulls DH\_ low and forces DL\_ high. This turns on the synchronous-rectifier MOSFETs with 100% duty, rapidly discharging the output capacitors and clamping both outputs to ground. However, immediately latching DL\_ high typically causes slightly negative output voltages due to the energy stored in the output LC at the instant the OVP occurs. If the load cannot tolerate a negative voltage, place a power Schottky diode across the output to act as a reverse-polarity clamp. If the condition that caused the overvoltage persists (such as a shorted high-side MOSFET), the battery blows. The other output is shut down using the soft-shutdown sequence. Cycle LDO5 below 1V or toggle either ON3, ON5, or SHDN to clear the fault latch and restart the SMPS controllers.

#### Output Undervoltage Protection (UVP)

Each SMPS controller includes an output UVP protection circuit that begins to monitor the output 6144 clock cycles (1 / fosc) after that output is enabled (ON\_pulled high). If either SMPS output voltage drops below 70% of its nominal regulation voltage and the UVP protection is enabled, the UVP circuit sets the fault latch, pulls PGOOD low, and shuts down both controllers using the soft-shutdown sequence. When an SMPS output voltage drops to 0.1V, its synchronous rectifier turns on, clamping the discharged output to GND. Cycle LDO5 below 1V or toggle either ON3, ON5, or SHDN to clear the fault latch and restart the SMPS controllers.

### Thermal-Fault Protection

The MAX8744A/MAX8745A feature a thermal fault-protection circuit. When the junction temperature rises above +160°C, a thermal sensor activates the fault latch, pulls PGOOD low, and shuts down both SMPS controllers using the soft-shutdown sequence. When an SMPS output voltage drops to 0.1V, its synchronous rectifier turns on, clamping the discharged output to GND. Toggle either ON3, ON5, or SHDN to clear the fault latch and restart the controllers after the junction temperature cools by 15°C.

\_ /N/IXI/N

### **Auxiliary LDO Detailed Description**

The MAX8744A/MAX8745A include an auxiliary linear regulator (OUTA) that can be configured for 12V, ideal for PCMCIA power requirements, and for biasing the gates of load switches in a portable device. OUTA can also be configured for outputs from 1V to 23V. The auxiliary regulator has an independent ON/OFF control, allowing it to be shut down when not needed, reducing power consumption when the system is in a low-power state.

A flyback-winding control loop regulates a secondary winding output, improving cross-regulation when the primary output is lightly loaded or when there is a low inputoutput differential voltage. If VDRVA < VOUTA, the low-side switch is turned on for a time equal to 33% of the switching period. This reverses the inductor (primary) current, pulling current from the output filter capacitor and causing the flyback transformer to operate in forward mode. The low impedance presented by the transformer secondary in forward mode dumps current into the secondary output, charging up the secondary capacitor and bringing VINA - VOUTA back into regulation. The secondary feedback loop does not improve secondary output accuracy in normal flyback mode, where the main (primary) output is heavily loaded. In this condition, secondary output accuracy is determined by the secondary rectifier drop, transformer turns ratio, and accuracy of the main output voltage.

## SMPS Design Procedure

Firmly establish the input voltage range and maximum load current before choosing a switching frequency and inductor operating point (ripple-current ratio). The primary design trade-off lies in choosing a good switching frequency and inductor operating point, and the following four factors dictate the rest of the design:

- Input Voltage Range. The maximum value (VIN(MAX)) must accommodate the worst-case, high AC-adapter voltage. The minimum value (VIN(MIN)) must account for the lowest battery voltage after drops due to connectors, fuses, and battery selector switches. If there is a choice at all, lower input voltages result in better efficiency.
- Maximum Load Current. There are two values to consider. The peak load current (ILOAD(MAX)) determines the instantaneous component stresses and filtering requirements and thus drives output capacitor selection, inductor saturation rating, and the design of the current-limit circuit. The continuous load current (ILOAD) determines the thermal stresses and thus drives the selection of input capacitors, MOSFETs, and other critical heat-contributing components.

- **Switching Frequency.** This choice determines the basic trade-off between size and efficiency. The optimal frequency is largely a function of maximum input voltage, due to MOSFET switching losses that are proportional to frequency and V<sub>IN</sub><sup>2</sup>. The optimum frequency is also a moving target, due to rapid improvements in MOSFET technology that are making higher frequencies more practical.
- Inductor Operating Point. This choice provides trade-offs between size vs. efficiency and transient response vs. output ripple. Low inductor values provide better transient response and smaller physical size, but also result in lower efficiency and higher output ripple due to increased ripple currents. The minimum practical inductor value is one that causes the circuit to operate at the edge of critical conduction (where the inductor current just touches zero with every cycle at maximum load). Inductor values lower than this grant no further size-reduction benefit. The optimum operating point is usually found between 20% and 50% ripple current. When pulse skipping (SKIP low and light loads), the inductor value also determines the load-current value at which PFM/PWM switchover occurs.

### **Inductor Selection**

The switching frequency and inductor operating point determine the inductor value as follows:

$$L = \frac{V_{OUT}(V_{IN} - V_{OUT})}{V_{IN}f_{OSC}I_{LOAD(MAX)}LIR}$$

For example:  $I_{LOAD(MAX)} = 5A$ ,  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $f_{OSC} = 300kHz$ , 30% ripple current or LIR = 0.3:

$$L = \frac{5V \times (12V - 5V)}{12V \times 300kHz \times 5A \times 0.3} = 6.50 \mu H$$

Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. Most inductor manufacturers provide inductors in standard values, such as 1.0µH, 1.5µH, 2.2µH, 3.3µH, etc. Also look for non-standard values, which can provide a better compromise in LIR across the input voltage range. If using a swinging inductor (where the no-load inductance decreases linearly with increasing current), evaluate the LIR with properly scaled inductance values. For the selected inductance value, the actual peak-to-peak inductor ripple current ( $\Delta I_{INDUCTOR}$ ) is defined by:

$$\Delta I_{INDUCTOR} = \frac{V_{OUT}(V_{IN} - V_{OUT})}{V_{IN}f_{OSC}L}$$

Ferrite cores are often the best choice, although powdered iron is inexpensive and can work well at 200kHz. The core must be large enough not to saturate at the peak inductor current (IPEAK):

$$I_{PEAK} = I_{LOAD(MAX)} + \frac{\Delta I_{INDUCTOR}}{2}$$

# Transformer Design (for MAX8744A/MAX8745A Auxiliary Output)

A coupled inductor or transformer can be substituted for the inductor in the 5V SMPS to create an auxiliary output (Figure 1). The MAX8744A/MAX8745A is particularly well suited for such applications because the secondary feedback threshold automatically triggers DL5 even if the 5V output is lightly loaded.

The power requirements of the auxiliary supply must be considered in the design of the main output. The transformer must be designed to deliver the required current in both the primary and the secondary outputs with the proper turns ratio and inductance. The power ratings of the synchronous-rectifier MOSFETs and the current limit in the MAX8744A/MAX8745A must also be adjusted accordingly. Extremes of low input-output differentials, widely different output loading levels, and high turns ratios can further complicate the design due to parasitic transformer parameters such as interwinding capacitance, secondary resistance, and leakage inductance. Power from the main and secondary outputs is combined to get an equivalent current referred to the main output. Use this total current to determine the current limit (see the Setting the Current Limit section):

where I<sub>TOTAL</sub> is the equivalent output current referred to the main output, and P<sub>TOTAL</sub> is the sum of the output power from both the main output and the secondary output:

$$N = \frac{V_{SEC} + V_{FWD}}{V_{OUT5} + V_{RECT} + V_{SENSE}}$$

where LPRIMARY is the primary inductance, N is the transformer turns ratio, VSEC is the minimum required rectified secondary voltage, VFWD is the forward drop across the secondary rectifier, VOUT5(MIN) is the minimum value of the main output voltage, and VRECT is the on-state voltage drop across the synchronous-rectifier MOSFET. The transformer secondary return is often connected to the main output voltage instead of ground in order to reduce the necessary turns ratio. In this case, subtract VOUT5 from the secondary voltage (VSEC - VOUT5) in the transformer turns-ratio equation above. The secondary diode in coupled-inductor applications must

withstand flyback voltages greater than 60V. Common silicon rectifiers, such as the 1N4001, are also prohibited because they are too slow. Fast silicon rectifiers such as the MURS120 are the only choice. The flyback voltage across the rectifier is related to the  $V_{\text{IN}}$  -  $V_{\text{OUT5}}$  difference, according to the transformer turns ratio:

where N is the transformer turns ratio (secondary windings/primary windings), and VSEC is the maximum secondary DC output voltage. If the secondary winding is returned to VOUT5 instead of ground, subtract VOUT5 from VFLYBACK in the equation above. The diode's reverse breakdown voltage rating must also accommodate any ringing due to leakage inductance. The diode's current rating should be at least twice the DC load current on the secondary output.

### **Transient Response**

The inductor ripple current also impacts transient-response performance, especially at low V<sub>IN</sub> - V<sub>OUT</sub> differentials. Low inductor values allow the inductor current to slew faster, replenishing charge removed from the output filter capacitors by a sudden load step. The total output voltage sag is the sum of the voltage sag while the inductor is ramping up, and the voltage sag before the next pulse can occur:

$$V_{SAG} = \frac{L(\Delta I_{LOAD(MAX)})^{2}}{2C_{OUT}(V_{IN} \times D_{MAX} - V_{OUT})} + \frac{\Delta I_{LOAD(MAX)}(T - \Delta T)}{C_{OUT}}$$

where D<sub>MAX</sub> is maximum duty factor (see the *Electrical Characteristics*), T is the switching period (1 / f<sub>OSC</sub>), and  $\Delta$ T equals V<sub>OUT</sub> / V<sub>IN</sub> x T when in PWM mode, or L x 0.2 x I<sub>MAX</sub> / (V<sub>IN</sub> - V<sub>OUT</sub>) when in skip mode. The amount of overshoot during a full-load to no-load transient due to stored inductor energy can be calculated as:

$$V_{SOAR} \approx \frac{\left(\Delta I_{LOAD(MAX)}\right)^2 L}{2C_{OUT}V_{OUT}}$$

### **Setting the Current Limit**

The minimum current-limit threshold must be great enough to support the maximum load current when the current limit is at the minimum tolerance value. The peak inductor current occurs at ILOAD(MAX) plus half the ripple current; therefore:

$$I_{LIMIT} > I_{LOAD(MAX)} + \left(\frac{\Delta I_{INDUCTOR}}{2}\right)$$

where  $I_{LIMIT}$  equals the minimum current-limit threshold voltage divided by the current-sense resistance (RSENSE\_). For the default setting, the minimum current-limit threshold is 45mV

Connect ILIM to LDO5 for a default 50mV current-limit threshold. In adjustable mode, the current-limit threshold is precisely 1/10 the voltage seen at ILIM. For an adjustable threshold, connect a resistive divider from REF to analog ground (GND) with ILIM connected to the center tap. The external 0.5V to 2V adjustment range corresponds to a 50mV to 200mV current-limit threshold. When adjusting the current limit, use 1% tolerance resistors and a divider current of approximately 10mA to prevent significant inaccuracy in the current-limit tolerance.

The current-sense method (Figure 7) and magnitude determines the achievable current-limit accuracy and power loss. Typically, higher current-sense limits provide tighter accuracy, but also dissipate more power. Most applications employ a current-limit threshold (VLIMIT) of 50mV to 100mV, so the sense resistor may be determined by:

$$R_{CS} = \frac{V_{LIMIT}}{I_{LIMIT}} = \frac{V_{ILIM}}{10 \times I_{LIMIT}}$$

For the best current-sense accuracy and overcurrent protection, use a 1% tolerance current-sense resistor between the inductor and output as shown in Figure 7A. This configuration constantly monitors the inductor

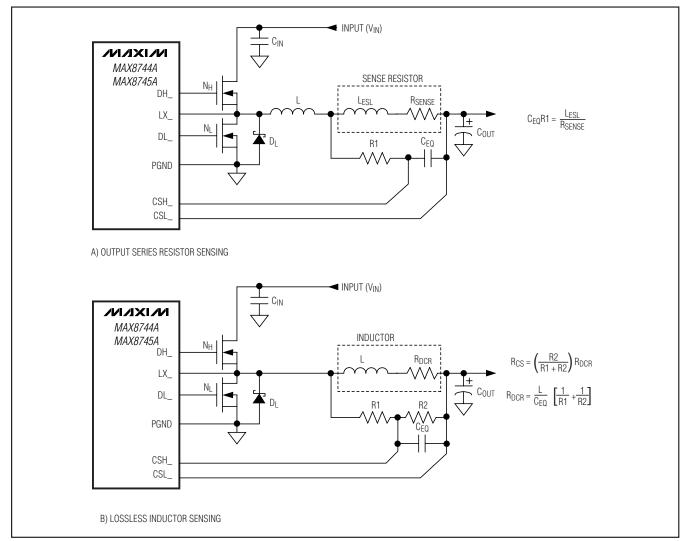


Figure 7. Current-Sense Configurations

current, allowing accurate current-limit protection. However, the parasitic inductance of the current-sense resistor can cause current-limit inaccuracies, especially when using low-value inductors and current-sense resistors. This parasitic inductance (LESL) can be canceled by adding an RC circuit across the sense resistor with an equivalent time constant:

$$C_{EQ}R1 = \frac{L_{ESL}}{R_{SENSE}}$$

Alternatively, high-power applications that do not require highly accurate current-limit protection may reduce the overall power dissipation by connecting a series RC circuit across the inductor (Figure 7B) with an equivalent time constant:

$$R_{CS} = \left(\frac{R2}{R1 + R2}\right) R_{DCR}$$

and:

$$R_{DCR} = \frac{L}{C_{EQ}} \left[ \frac{1}{R1} + \frac{1}{R2} \right]$$

where RCs is the required current-sense resistance, and RDCR is the inductor's series DC resistance. Use the typical inductance and RDCR values provided by the inductor manufacturer.

#### **Output Capacitor Selection**

The output filter capacitor must have low enough equivalent series resistance (ESR) to meet output ripple and load-transient requirements, yet have high enough ESR to satisfy stability requirements. The output capacitance must be high enough to absorb the inductor energy while transitioning from full-load to no-load conditions without tripping the overvoltage fault protection. When using high capacitance, low-ESR capacitors (see stability requirements), the filter capacitor's ESR dominates the output voltage ripple. So the output capacitor's size depends on the maximum ESR required to meet the output voltage ripple (VRIPPLE(P-P)) specifications:

$$V_{RIPPLE(P-P)} = RESRILOAD(MAX)LIR$$

In idle mode, the inductor current becomes discontinuous, with peak currents set by the idle mode current-sense threshold ( $V_{\rm IDLE} = 0.2V_{\rm LIMIT}$ ). In idle mode, the no-load output ripple may be determined as follows:

$$V_{RIPPLE(P-P)} = \frac{V_{IDLE}R_{ESR}}{R_{SENSE}}$$

The actual capacitance value required relates to the physical size needed to achieve low ESR, as well as to the chemistry of the capacitor technology. Thus, the capacitor is usually selected by ESR and voltage rating rather than by capacitance value (this is true of tantalums, OS-CONs, polymers, and other electrolytics). When using low-capacity filter capacitors, such as ceramic capacitors, size is usually determined by the capacity needed to prevent VSAG and VSOAR from causing problems during load transients. Generally, once enough capacitance is added to meet the overshoot requirement, undershoot at the rising load edge is no longer a problem (see the VSAG and VSOAR equations in the Transient Response section). However, lowcapacity filter capacitors typically have high ESR zeros that may affect the overall stability (see the Output-Capacitor Stability Considerations section).

### Output-Capacitor Stability Considerations

Stability is determined by the value of the ESR zero relative to the switching frequency. The boundary of instability is given by the following equation:

$$f_{ESR} \le \frac{f_{OSC}}{\pi}$$

where:

$$f_{ESR} = \frac{1}{2\pi R_{ESR} C_{OUT}}$$

For a typical 300kHz application, the ESR zero frequency must be well below 95kHz, preferably below 50kHz. Tantalum and OS-CON capacitors in widespread use at the time of publication have typical ESR zero frequencies of 25kHz. In the design example used for inductor selection, the ESR needed to support 25mVp-pripple is 25mV/1.5A = 16.7m $\Omega$ . One 220µF/4V Sanyo polymer (TPE) capacitor provides 15m $\Omega$  (max) ESR. This results in a zero at 48kHz, well within the bounds of stability.

For low-input voltage applications where the duty cycle exceeds 50% ( $V_{OUT}/V_{IN} \ge 50\%$ ), the output ripple voltage should not be greater than twice the internal slope-compensation voltage:

where VRIPPLE equals  $\Delta I_{INDUCTOR} \times RESR$ . The worst-case ESR limit occurs when  $V_{IN} = 2 \times V_{OUT}$ , so the above equation may be simplified to provide the following boundary condition:

 $RESR \le 0.04 \times L \times fSW$ 

Do not put high-value ceramic capacitors directly across the feedback sense point without taking precautions to ensure stability. Large ceramic capacitors can have a high ESR zero frequency and cause erratic, unstable operation. However, it is easy to add enough series resistance by placing the capacitors a couple of inches downstream from the feedback sense point, which should be as close as possible to the inductor.

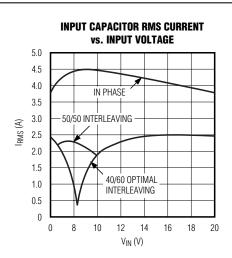
Unstable operation manifests itself in two related, but distinctly different ways: short/long pulses and cycle skipping, which results in lower frequency operation. Instability occurs due to noise on the output or because the ESR is so low that there is not enough voltage ramp in the output voltage signal. This "fools" the error comparator into triggering too early or into skipping a cycle. Cycle skipping is more annoying than harmful, resulting in nothing worse than increased output ripple. However, it can indicate the possible presence of loop instability due to insufficient ESR. Loop instability can

result in oscillations at the output after line or load steps. Such perturbations are usually damped, but can cause the output voltage to rise above or fall below the tolerance limits.

The easiest method for checking stability is to apply a very fast zero-to-max load transient and carefully observe the output-voltage-ripple envelope for overshoot and ringing. It may help to simultaneously monitor the inductor current with an AC current probe. Do not allow more than three cycles of ringing after the initial step-response under/overshoot.

### **Input Capacitor Selection**

The input capacitor must meet the ripple current requirement (I<sub>RMS</sub>) imposed by the switching currents. For an out-of-phase regulator, the total RMS current in the input capacitor is a function of the load currents, the input currents, the duty cycles, and the amount of overlap as defined in Figure 8.



INPUT RMS CURRENT FOR INTERLEAVED OPERATION:

$$I_{RMS} = \sqrt{\left(\text{OUT5} - I_{IN}\right)^2 \left(\text{D}_{LX5} - \text{D}_{OL}\right) + \left(\text{I}_{OUT3} - I_{IN}\right)^2 \left(\text{D}_{LX3} - \text{D}_{OL}\right) + \left(\text{I}_{OUT5} + I_{OUT3} - I_{IN}\right)^2 \text{D}_{OL} + I_{IN}^2 \left(1 - \text{D}_{LX5} - \text{D}_{LX3} + \text{D}_{OL}\right)}}$$

$$D_{LX5} = \frac{V_{OUT5}}{V_{IN}} \qquad D_{LX3} = \frac{V_{OUT3}}{V_{IN}} \qquad D_{OL} = \text{DUTY-CYCLE OVERLAP FRACTION}$$

$$I_{IN} = \frac{V_{OUT5}I_{OUT5} + V_{OUT3}I_{OUT3}}{V_{IN}}$$

VIN INPUT RMS CURRENT FOR SINGLE-PHASE OPERATION:

 $I_{RMS} = I_{LOAD} \left( \frac{\sqrt{V_{OUT}(V_{IN} - V_{OUT})}}{V_{IN}} \right)$ 

Figure 8. Input RMS Current



The 40/60 optimal interleaved architecture of the MAX8744A/MAX8745A allows the input voltage to go as low 8.3V before the duty cycles begin to overlap. This offers improved efficiency over a regular 180° out-of-phase architecture where the duty cycles begin to overlap below 10V. Figure 8 shows the input-capacitor RMS current vs. input voltage for an application that requires 5V/5A and 3.3V/5A. This shows the improvement of the 40/60 optimal interleaving over 50/50 interleaving and in-phase operation.

For most applications, nontantalum chemistries (ceramic, aluminum, or OS-CON) are preferred due to their resistance to power-up surge currents typical of systems with a mechanical switch or connector in series with the input. Choose a capacitor that has less than 10°C temperature rise at the RMS input current for optimal reliability and lifetime.

#### **Power-MOSFET Selection**

Most of the following MOSFET guidelines focus on the challenge of obtaining high load-current capability when using high-voltage (> 20V) AC adapters. Low-current applications usually require less attention.

The high-side MOSFET (N<sub>H</sub>) must be able to dissipate the resistive losses plus the switching losses at both VIN(MIN) and VIN(MAX). Ideally, the losses at VIN(MIN) should be roughly equal to the losses at VIN(MAX), with lower losses in between. If the losses at VIN(MIN) are significantly higher, consider increasing the size of N<sub>H</sub>. Conversely, if the losses at VIN(MAX) are significantly higher, consider reducing the size of N<sub>H</sub>. If VIN does not vary over a wide range, maximum efficiency is achieved by selecting a high-side MOSFET (N<sub>H</sub>) that has conduction losses equal to the switching losses.

Choose a low-side MOSFET (N<sub>L</sub>) that has the lowest possible on-resistance (R<sub>DS(ON)</sub>), comes in a moderate-sized package (i.e., 8-pin SO, DPAK, or D<sup>2</sup>PAK), and is reasonably priced. Ensure that the MAX8744A/MAX8745A DL\_gate driver can supply sufficient current to support the gate charge and the current injected into the parasitic drain-to-gate capacitor caused by the high-side MOSFET turning on; otherwise, cross-conduction problems may occur. Switching losses are not an issue for the low-side MOSFET since it is a zero-voltage switched device when used in the step-down topology.

#### Power-MOSFET Dissipation

Worst-case conduction losses occur at the duty-factor extremes. For the high-side MOSFET (N<sub>H</sub>), the worst-case power dissipation due to resistance occurs at minimum input voltage:

PD (N<sub>H</sub> Resistive) = 
$$\left(\frac{V_{OUT}}{V_{IN}}\right) (I_{LOAD})^2 R_{DS(ON)}$$

Generally, use a small high-side MOSFET to reduce switching losses at high input voltages. However, the RDS(ON) required to stay within package power-dissipation limits often limits how small the MOSFET can be. The optimum occurs when the switching losses equal the conduction (RDS(ON)) losses. High-side switching losses do not become an issue until the input is greater than approximately 15V.

Calculating the power dissipation in high-side MOSFETs (N<sub>H</sub>) due to switching losses is difficult, since it must allow for difficult-to-quantify factors that influence the turnon and turn-off times. These factors include the internal gate resistance, gate charge, threshold voltage, source inductance, and PCB layout characteristics. The following switching-loss calculation provides only a very rough estimate and is no substitute for breadboard evaluation, preferably including verification using a thermocouple mounted on N<sub>H</sub>:

$$PD (N_{H} Switching) = \left(\frac{I_{LOAD}Q_{G(SW)}}{I_{GATE}} + \frac{C_{OSS}V_{IN(MAX)}}{2}\right)V_{IN(MAX)}f_{SW}$$

where Coss is the output capacitance of N<sub>H</sub>,  $Q_{G(SW)}$  is the charge needed to turn on the N<sub>H</sub> MOSFET, and I<sub>GATE</sub> is the peak gate-drive source/sink current (1A typ).

Switching losses in the high-side MOSFET can become a heat problem when maximum AC adapter voltages are applied, due to the squared term in the switching-loss equation (C x  $V_{IN}^2$  x fsw). If the high-side MOSFET chosen for adequate RDS(ON) at low battery voltages becomes extraordinarily hot when subjected to  $V_{IN(MAX)}$ , consider choosing another MOSFET with lower parasitic capacitance.

For the low-side MOSFET (N<sub>L</sub>), the worst-case power dissipation always occurs at maximum battery voltage:

PD (N<sub>L</sub> Resistive) = 
$$\left[1 - \left(\frac{V_{OUT}}{V_{IN(MAX)}}\right)\right] (I_{LOAD})^2 R_{DS(ON)}$$

The absolute worst case for MOSFET power dissipation occurs under heavy overload conditions that are greater than ILOAD(MAX), but are not high enough to exceed the current limit and cause the fault latch to trip. To protect against this possibility, "overdesign" the circuit to tolerate:

$$I_{LOAD} = I_{LIMIT} - \left(\frac{\Delta I_{INDUCTOR}}{2}\right)$$

where I<sub>LIMIT</sub> is the peak current allowed by the current-limit circuit, including threshold tolerance and sense-resistance variation. The MOSFETs must have a relatively large heatsink to handle the overload power dissipation.

Choose a Schottky diode (D<sub>L</sub>) with a forward-voltage drop low enough to prevent the low-side MOSFET's body diode from turning on during the dead time. As a general rule, select a diode with a DC current rating equal to a 1/3 the load current. This diode is optional and can be removed if efficiency is not critical.

### **Boost Capacitors**

The boost capacitors (CBST) must be selected large enough to handle the gate-charging requirements of the high-side MOSFETs. Typically,  $0.1\mu F$  ceramic capacitors work well for low-power applications driving medium-sized MOSFETs. However, high-current applications driving large, high-side MOSFETs require boost capacitors larger than  $0.1\mu F$ . For these applications, select the boost capacitors to avoid discharging the capacitor more than 200mV while charging the high-side MOSFETs' gates:

$$C_{BST} = \frac{Q_{GATE}}{200mV}$$

where QGATE is the total gate charge specified in the high-side MOSFET's data sheet. For example, assume the FDS6612A n-channel MOSFET is used on the high side. According to the manufacturer's data sheet, a single FDS6612A has a maximum gate charge of 13nC ( $V_{\rm GS}=5V$ ). Using the above equation, the required boost capacitance would be:

$$C_{BST} = \frac{13nC}{200mV} = 0.065 \mu F$$

Selecting the closest standard value, this example requires a  $0.1\mu F$  ceramic capacitor.

## **LDOA Design Procedure**

## **Output Voltage Selection**

Adjust the auxiliary linear regulator's output voltage by connecting a resistive divider between OUTA and analog ground with the center tap connected to FBA (Figure 1). Select R6 in the  $10k\Omega$  to  $30k\Omega$  range, and calculate R5 with the following equation:

$$R5 = R6 \left( \frac{V_{OUTA}}{V_{FBA}} - 1 \right)$$

where  $V_{FBA} = 1.0V$ .

#### **Transistor Selection**

The pass transistor must meet specifications for current gain  $(\beta)$ , input capacitance, collector-emitter saturation voltage, and power dissipation. The transistor's current gain limits the guaranteed maximum output current to:

$$I_{LOAD(MAX)} = \left(I_{DRV} - \frac{V_{BE}}{R_{BE}}\right) \beta_{MIN}$$

where IDRV is the minimum guaranteed base drive current, VBE is the base-to-emitter voltage of the transistor, and RBE is the pullup resistor connected between the transistor's base and emitter. Furthermore, the transistor's current gain increases the linear regulator's DC loop gain (see the *LDOA Stability Requirements* section), so excessive gain destabilizes the output. Therefore, transistors with current gain over 100 at the maximum output current can be difficult to stabilize and are not recommended. The transistor's input capacitance and input resistance also create a second pole, which could be low enough to make the output unstable when heavily loaded.

The transistor's saturation voltage at the maximum output current determines the minimum input-to-output voltage differential that the linear regulator supports. Alternatively, the package's power dissipation could limit the useable maximum input-to-output voltage differential. The maximum power dissipation capability of the transistor's package and mounting must exceed the actual power dissipation in the device. The power dissipation equals the maximum load current times the maximum input-to-output differential:

#### **LDOA Stability Requirements**

The MAX8744A/MAX8745A linear-regulator controller uses an internal transconductance amplifier to drive an external pnp pass transistor. The transconductance amplifier, the pass transistor, the base-to-emitter resistor, and the output capacitor determine the loop stability.

The transconductance amplifier regulates the output voltage by controlling the pass transistor's base current. The total DC loop gain is approximately:

$$A_{V(LDO)} = \left(\frac{5.5V}{V_T}\right) \left(1 + \frac{I_{BIAS} I_{FE}}{I_{LOAD}}\right)$$

where V<sub>T</sub> is 26mV at room temperature, h<sub>FE</sub> is the pass transistor's DC gain, and I<sub>BIAS</sub> is the current through the base-to-emitter resistor (R<sub>BE</sub>). The  $680\Omega$  base-to-emitter resistor used in Figure 1 was chosen to provide a 1mA bias current (I<sub>BIAS</sub>).

The output capacitor and the load resistance create the dominant pole in the system. However, the internal amplifier delay, the pass transistor's input capacitance, and the stray capacitance at the feedback node create additional poles in the system, and the output capacitor's ESR generates a zero. For proper operation, use the following steps to ensure the linear-regulator stability:

1) First, calculate the dominant pole set by the linear regulator's output capacitor and the load resistor:

$$f_{POLE(LDO)} = \frac{1}{2\pi C_{OLITA}R_{LOAD}}$$

where C<sub>OUTA</sub> is the output capacitance of the auxiliary LDO and R<sub>LOAD</sub> is the load resistance corresponding to the maximum load current. The unitygain crossover of the linear regulator is:

$$fCROSSOVER = AV(LDO)fPOLE(LDO)$$

The pole caused by the internal amplifier delay is at approximately 1MHz:

3) Next, calculate the pole set by the transistor's input capacitance, the transistor's input resistance, and the base-to-emitter pullup resistor. Since the transistor's input resistance (hFE/gm) is typically much greater than the base-to-emitter pullup resistance, the pole can be determined from the simplified equation:

$$f_{POLE(CIN)} \approx \frac{1}{2\pi C_{IN}R_{IN}}$$
$$C_{IN} = \frac{g_m}{2\pi f_r}$$

where  $g_m$  is the transconductance of the pass transistor, and  $f_T$  is the transition frequency. Both parameters can be found in the transistor's data sheet. Therefore, the equation can be further reduced to:

$$f_{POLE(CIN)} \approx \frac{f_{T}}{h_{FF}}$$

4) Next, calculate the pole set by the linear regulator's feedback resistance and the capacitance between FBA and ground (approximately 5pF including stray capacitance):

$$f_{POLE(FBA)} = \frac{1}{2\pi C_{FBA}(R5 \parallel R6)}$$

5) Next, calculate the zero caused by the output capacitor's ESR:

$$f_{ZERO(ESR)} = \frac{1}{2\pi C_{OUTA}R_{ESR}}$$

where  $\ensuremath{\mathsf{RESR}}$  is the equivalent series resistance of  $\ensuremath{\mathsf{COUTA}}.$ 

6) To ensure stability, choose COUTA large enough so that the crossover occurs well before the poles and zero calculated in steps 2 through 5. The poles in steps 3 and 4 generally occur at several MHz, and using ceramic output capacitors ensures the ESR zero occurs at several MHz as well. Placing the crossover frequency below 500kHz is typically sufficient to avoid the amplifier delay pole and generally works well, unless unusual component selection or extra capacitance moves the other poles or zero below 1MHz.

A capacitor connected between the linear regulator's output and the feedback node can improve the transient response and reduce the noise coupled into the feedback loop.

If a low-dropout solution is required, an external p-channel MOSFET pass transistor could be used. However, a pMOS-based linear regulator requires higher output capacitance to stabilize the loop. The high gate capacitance of the p-channel MOSFET lowers the fPOLE(CIN) and can cause instability. A large output capacitance must be used to reduce the unity-gain bandwidth and ensure that the pole is well above the unity-gain crossover frequency.

## \_Applications Information

## **Duty-Cycle Limits**

#### Minimum Input Voltage

The minimum input operating voltage (dropout voltage) is restricted by the maximum duty-cycle specification (see the *Electrical Characteristics* table). However, keep in mind that the transient performance gets worse as the step-down regulators approach the dropout voltage, so bulk output capacitance must be added (see the voltage sag and soar equations in the *Transient Response* section of the *SMPS Design Procedure* section). The absolute point of dropout occurs when the inductor current ramps down during the off-time ( $\Delta IDOWN$ ) as much as it ramps up during the on-time ( $\Delta IUP$ ). This results in a minimum operating voltage defined by the following equation:

$$V_{IN(MIN)} = V_{OUT} + V_{CHG} + h \left( \frac{1}{D_{MAX}} - 1 \right) (V_{OUT} + V_{DIS})$$

where  $V_{CHG}$  and  $V_{DIS}$  are the parasitic voltage drops in the charge and discharge paths, respectively. A reasonable minimum value for h is 1.5, while the absolute minimum input voltage is calculated with h = 1.

### Maximum Input Voltage

The MAX8744A/MAX8745A controllers include a minimum on-time specification, which determines the maximum input operating voltage that maintains the selected switching frequency (see the *Electrical Characteristics* table). Operation above this maximum input voltage results in pulse-skipping operation, regardless of the operating mode selected by SKIP. At the beginning of each cycle, if the output voltage is still above the feedback threshold voltage, the controller does not trigger an on-time pulse, effectively skipping a cycle. This allows the controller to maintain regulation above the maximum input voltage, but forces the controller to effectively operate with a lower switching frequency. This results in an input threshold voltage at which the controller begins to skip pulses (VIN(SKIP)):

$$V_{IN(SKIP)} = V_{OUT} \left( \frac{1}{f_{OSC}t_{ON(MIN)}} \right)$$

where fosc is the switching frequency selected by FSEL.

#### **PCB Layout**

Careful PCB layout is critical to achieving low switching losses and clean, stable operation. The switching power stage requires particular attention (Figure 9). If possible, mount all the power components on the top side of the board, with their ground terminals flush against one another. Follow these guidelines for good PCB layout:

- Keep the high-current paths short, especially at the ground terminals. This practice is essential for stable, jitter-free operation.
- Keep the power traces and load connections short.
   This practice is essential for high efficiency. Using thick copper PCBs (2oz vs. 1oz) can enhance full-load efficiency by 1% or more. Correctly routing

PCB traces is a difficult task that must be approached in terms of fractions of centimeters, where a single milliohm of excess trace resistance causes a measurable efficiency penalty.

- Minimize current-sensing errors by connecting CSH\_ and CSL\_ directly across the current-sense resistor (RSENSE).
- When trade-offs in trace lengths must be made, it is preferable to allow the inductor charging path to be made longer than the discharge path. For example, it is better to allow some extra distance between the input capacitors and the high-side MOSFET than to allow distance between the inductor and the lowside MOSFET or between the inductor and the output filter capacitor.
- Route high-speed switching nodes (BST\_, LX\_, DH\_, and DL\_) away from sensitive analog areas (REF, FB\_, CSH\_, CSL\_).

## Layout Procedure

Place the power components first, with ground terminals adjacent (N<sub>L</sub> source, C<sub>IN</sub>, C<sub>OUT</sub>, and D<sub>L</sub> anode). If possible, make all these connections on the top layer with wide, copper-filled areas.

Mount the controller IC adjacent to the low-side MOSFET, preferably on the back side opposite  $N_{L}$  and  $N_{H}$  to keep LX\_, GND, DH\_, and the DL\_ gate-drive lines short and wide. The DL\_ and DH\_ gate traces must be short and wide (50 mils to 100 mils wide if the MOSFET is 1in from the controller IC) to keep the driver impedance low and for proper adaptive dead-time sensing.

Group the gate-drive components (BST\_ capacitor, LDO5 bypass capacitor) together near the controller IC.

Make the DC-DC controller ground connections as shown in Figures 1 and 9. This diagram can be viewed as having two separate ground planes: power ground, where all the high-power components go, and an analog ground plane for sensitive analog components. The analog ground plane and power ground plane must meet only at a single point directly at the IC.

Connect the output power planes directly to the output filter capacitor positive and negative terminals with multiple vias. Place the entire DC-DC converter circuit as close to the load as is practical.

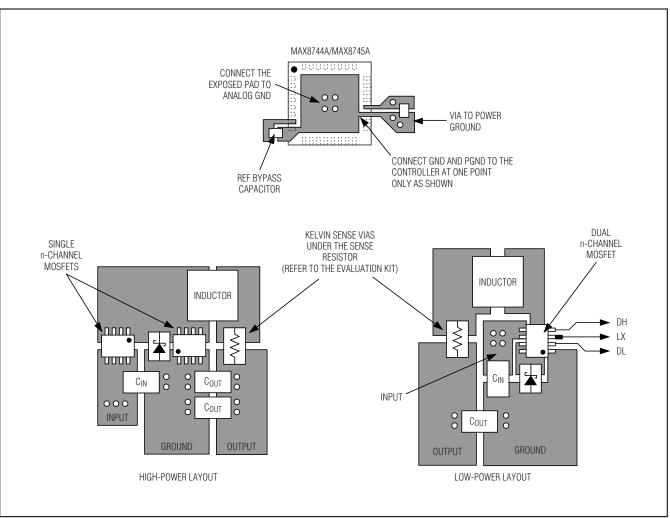


Figure 9. PCB Layout

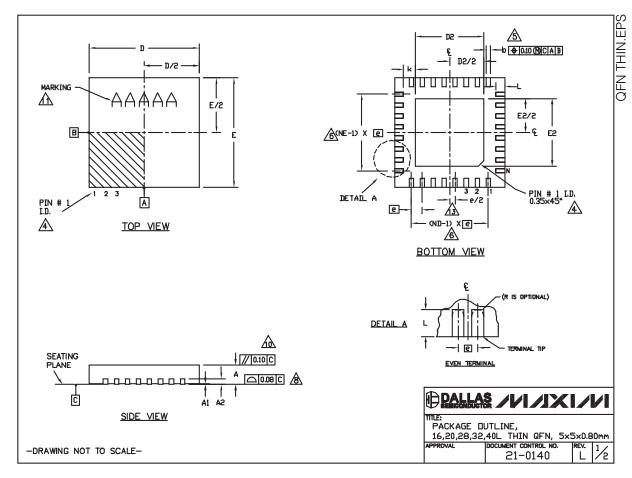
**Chip Information** 

**TRANSISTOR COUNT: 6897** 

PROCESS: BICMOS

## **Package Information**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)

	COMMON DIMENSIONS														
PKG.	16L 5×5		20L 5×5			29L 5x5		32L 5×5			40L 5×5				
SYMBOL	MIN.	NDM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NDM.	MAX.
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05
A2	0.20 REF.		F.	0.2	20 RE	F.	0.2	20 RE	F.	0.2	20 RE	F.	0.20 REF.		
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.20	0.25	0.30	0.15	0.20	0.25
D	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10
Ε	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5,00	5.10	4.90	5.00	5.10
e	0.	80 B	SC.	0.	65 B	SC.	0.50 BSC.		0.50 BSC.		SC.	0.40 BSC.			
k	0.25	-	-	0.25	-	-	0.25	_	-	0.25	-	-	0.25	-	-
L	0.30	0.40	0.50	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50	0.30	0.40	0.50
N	16				20		28		32		40				
ND	4			5			7		8			10			
NE	4			5			7		8		10				
JEDEC	\\	WHHB		١	√HHC		WHHD-1		VHHD-2						

- . DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS, ANGLES ARE IN DEGREES.
- 3. N IS THE TOTAL NUMBER OF TERMINALS.
- THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JESO 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED VITHIN THE ZONE INDICATED, THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
- DIMENSION to APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
- ⚠ ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
- 7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- ⚠ COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- 9. DRAWING CONFORMS TO JEDEC MO220, EXCEPT EXPOSED PAD DIMENSION FOR
- T2855-3, T2855-6, T4055-1 AND T4055-2.

  WARPAGE SHALL NOT EXCEED 0.10 mm.
- 11. MARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.
- 12. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.
- (1.05. LEAD CENTERLINES TO BE AT TRUE POSITION AS DEFINED BY BASIC DIMENSION 'e', ±0.05.
- 14. ALL DIMENSIONS APPLY TO BOTH LEADED AND PHFREE PARTS.

-DRAWING NOT TO SCALE-

EXPOSED PAD VARIATIONS									
PKG.		D2		E2					
CODES	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.			
T1655-2	3.00	3.10	3.20	3.00	3.10	3.20			
T1655-3	3.00	3.10	3.20	3.00	3.10	3.20			
T1655N-1	3.00	3.10	3.20	3.00	3.10	3.20			
T2055-3	3.00	3.10	3.20	3.00	3.10	3.20			
T2055-4	3.00	3.10	3.20	3.00	3.10	3.20			
T2055-5	3.15	3.25	3.35	3.15	3.25	3.35			
T2055MN-5	3.15	3.25	3.35	3.15	3.25	3.35			
T2855-3	3.15	3.25	3.35	3.15	3.25	3.35			
T2955-4	2.60	2.70	2.80	2.60	2.70	2.80			
T2855-5	2.60	2.70	2.80	2.60	2.70	2.80			
T2855-6	3.15	3.25	3.35	3.15	3.25	3.35			
T2855-7	2.60	2.70	2.80	2.60	2.70	2.80			
T2955-8	3.15	3.25	3.35	3.15	3.25	3.35			
T2855N-1	3.15	3.25	3.35	3.15	3.25	3.35			
T3255-3	3.00	3.10	3.20	3.00	3.10	3.20			
T3255-4	3.00	3.10	3.20	3.00	3.10	3.20			
T3255M-4	3.00	3.10	3.20	3.00	3.10	3.20			
T3255-5	3.00	3.10	3.20	3.00	3.10	3.20			
T3255N-1	3.00	3.10	3.20	3.00	3.10	3.20			
T4055-1	3.40	3.50	3.60	3.40	3.50	3.60			
T4055-2	3,40	3,50	3.60	3,40	3.50	3.60			
T4055MN-1	3.40	3.50	3.60	3.40	3.50	3.60			



16,20,28,32,40L THIN QFN, 5x5x0.80mm

APPROVAL | DOCUMENT CONTROL NO. | REV. | 2/2

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